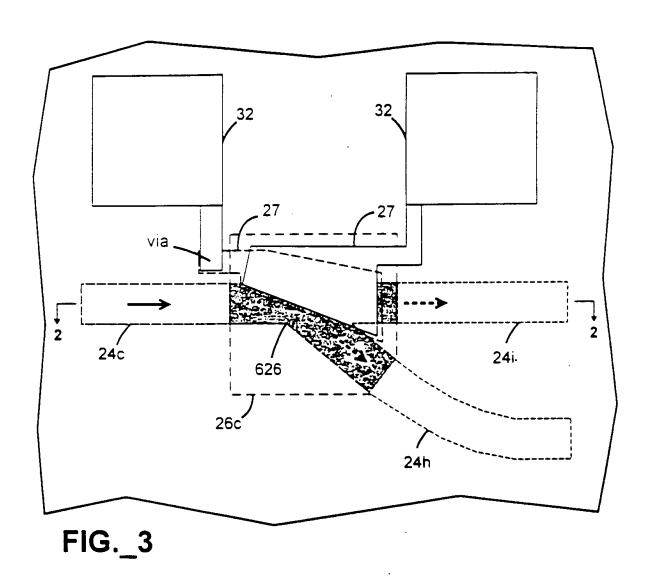


FIG._2



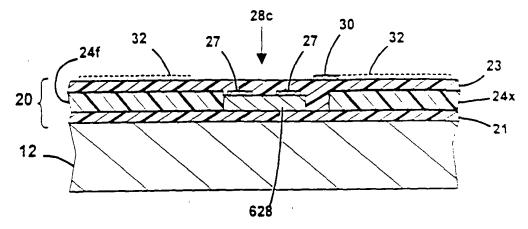


FIG._4-1

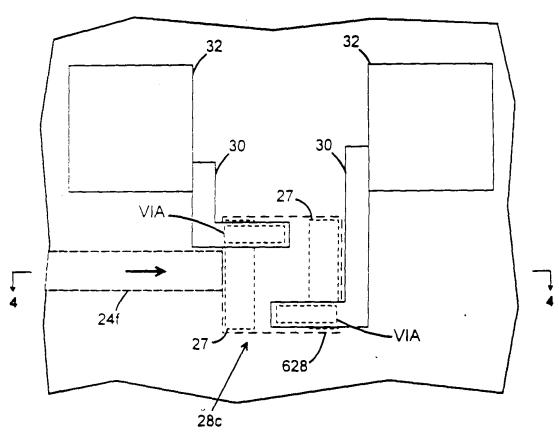
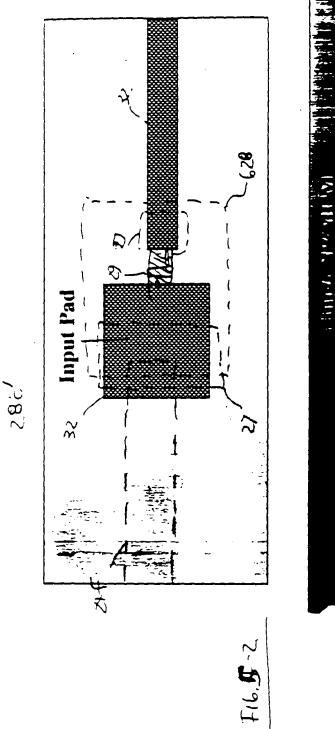
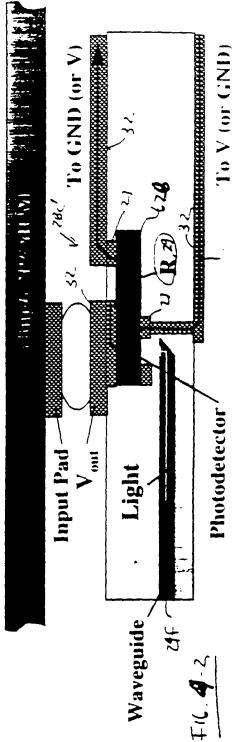
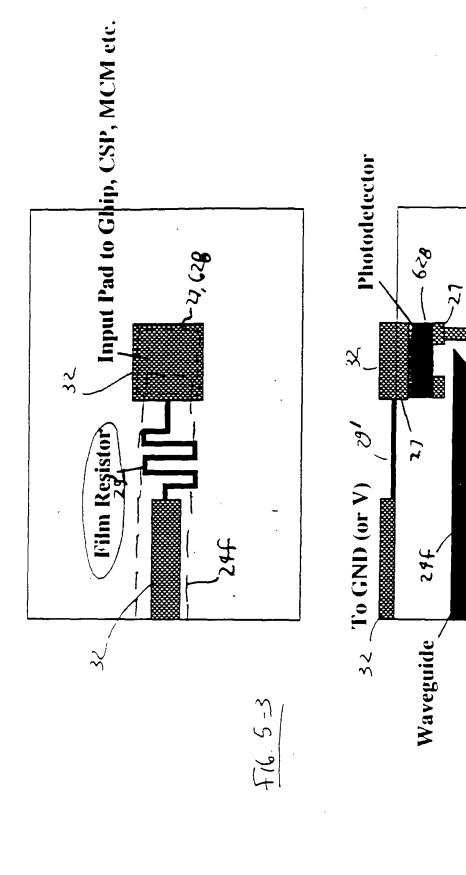


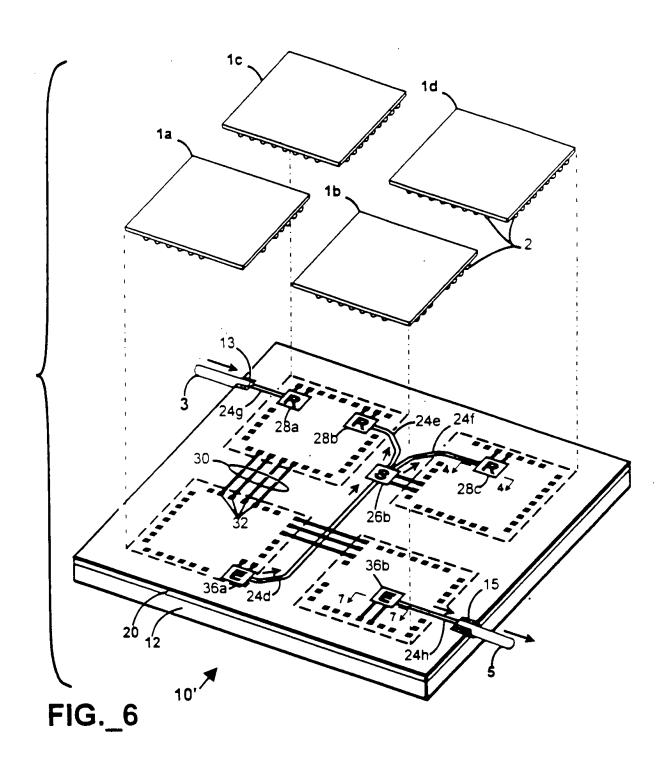
FIG._5-1







To V (or GRND)



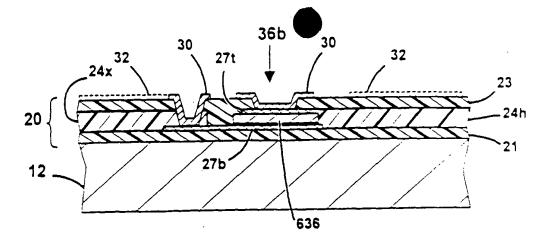


FIG._7

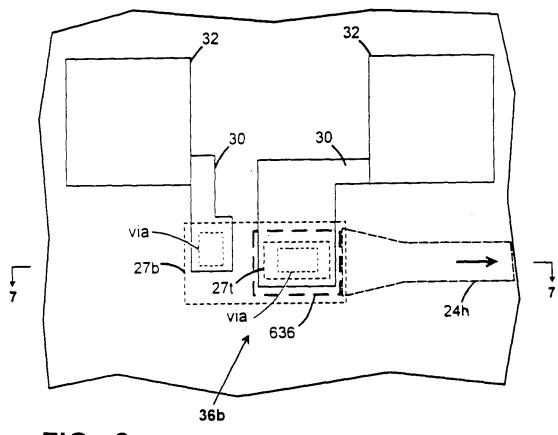
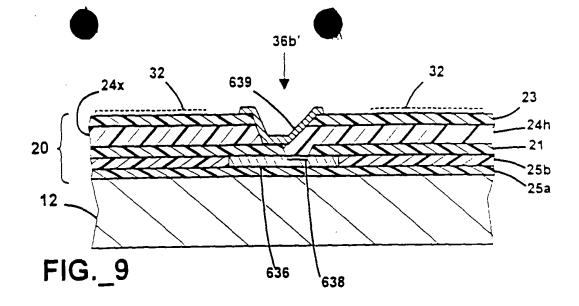


FIG._8



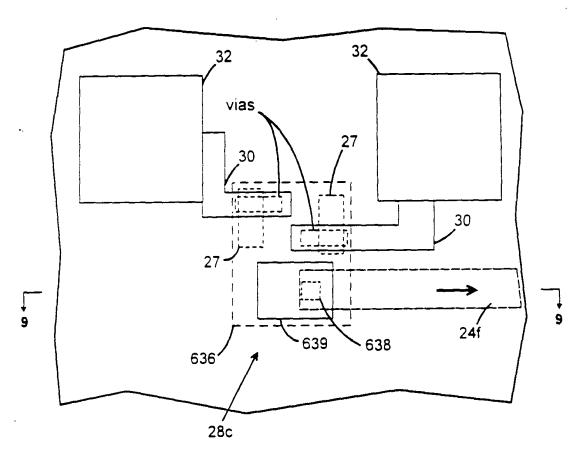
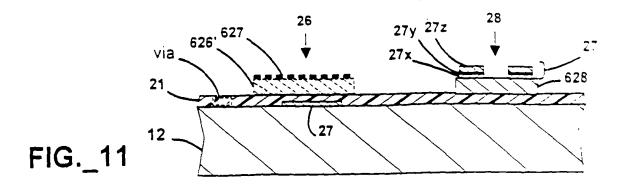
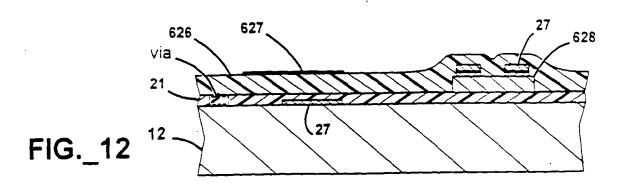
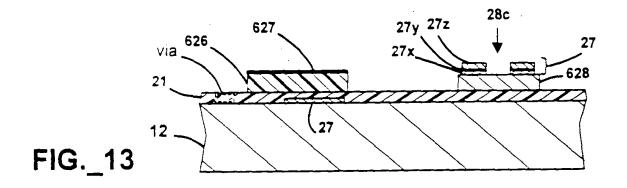
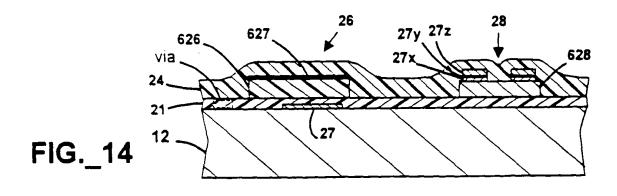


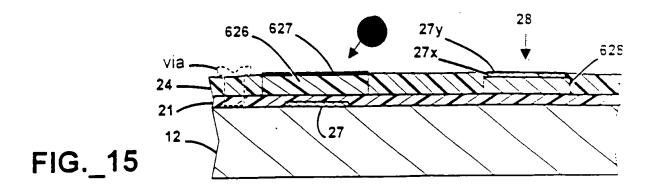
FIG._10

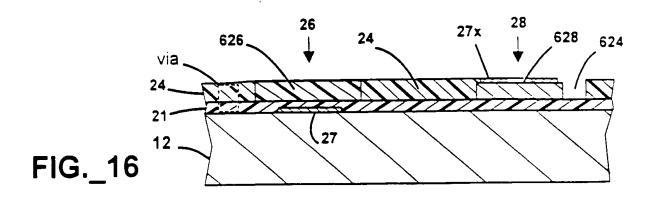


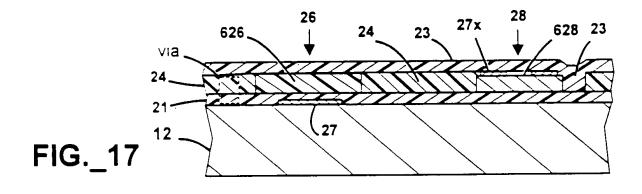


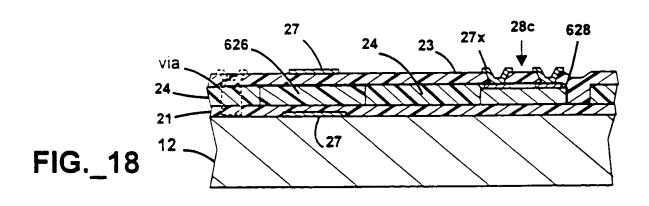












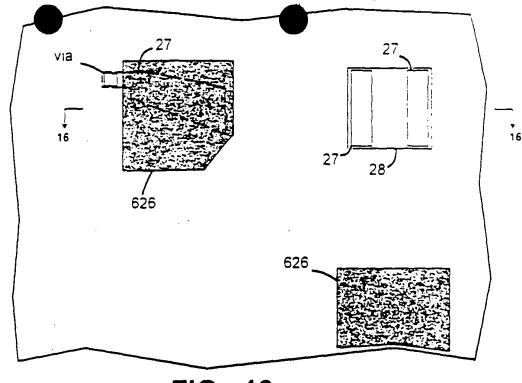


FIG._19

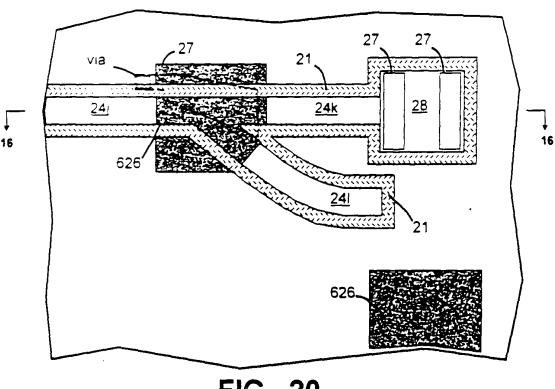


FIG._20

FIG. 2

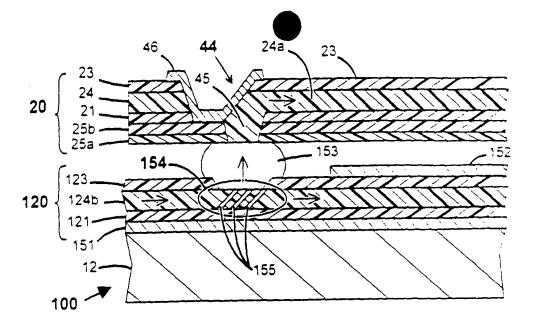


FIG._22

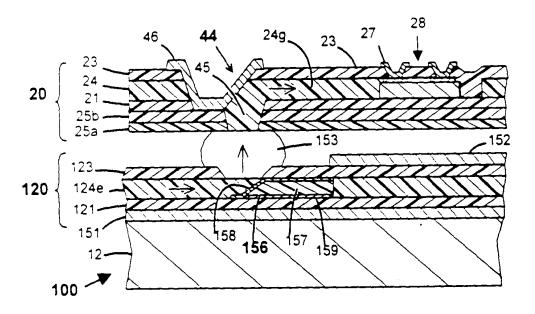


FIG._23

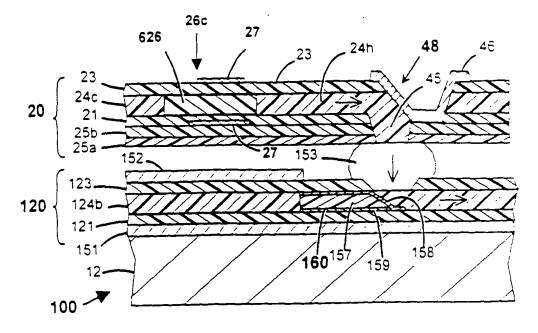
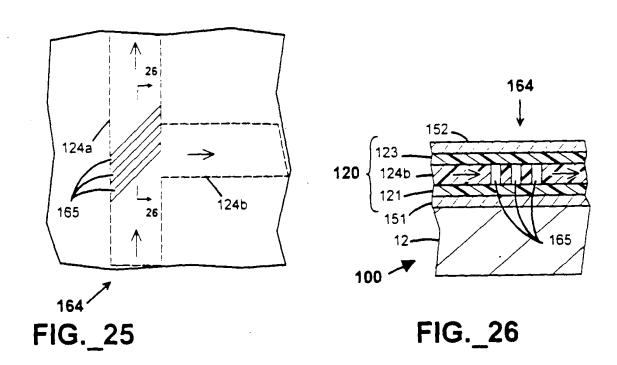
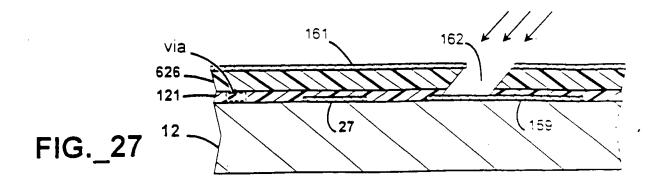
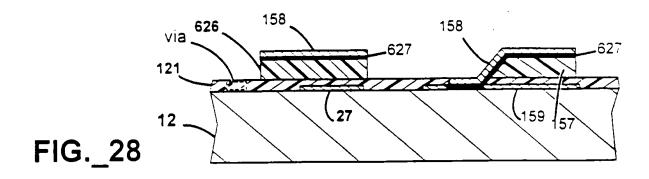
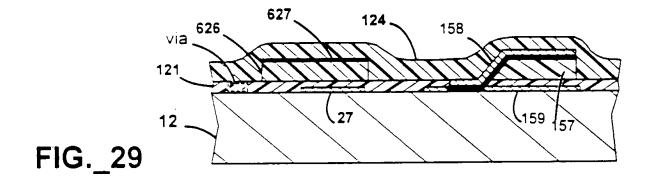


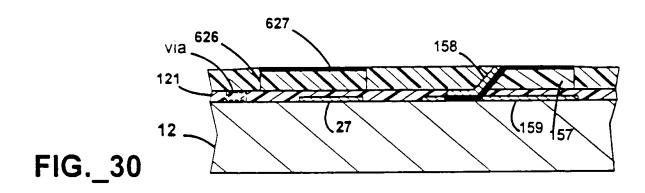
FIG._24

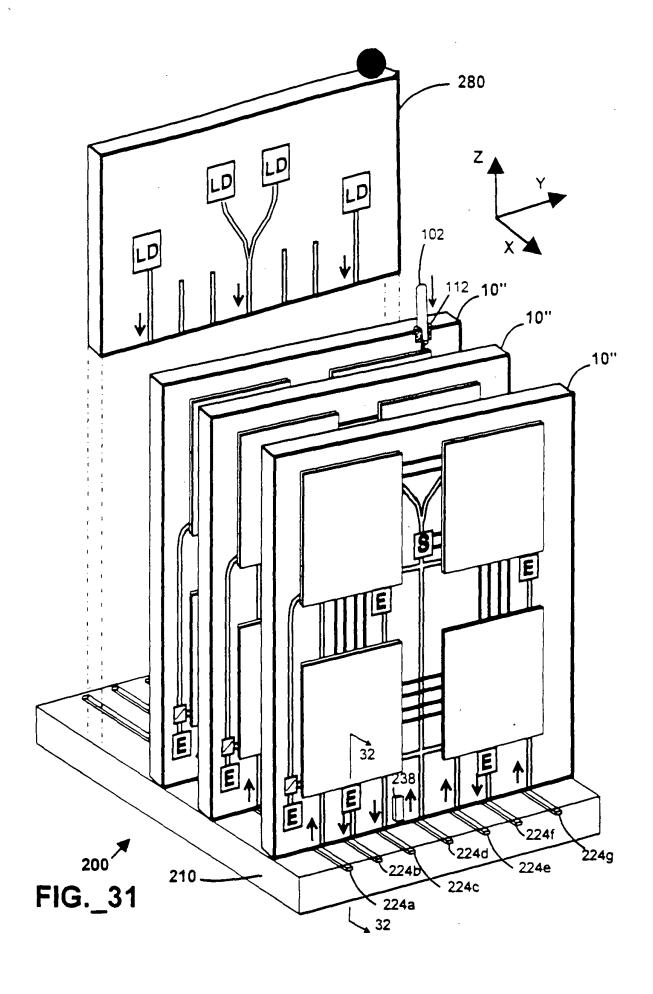


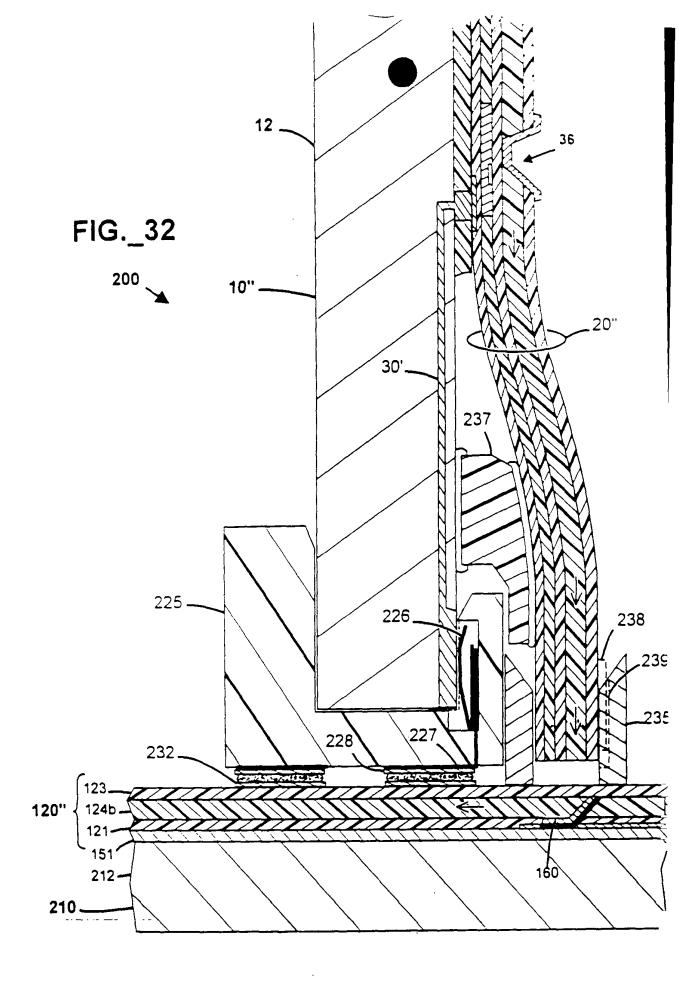


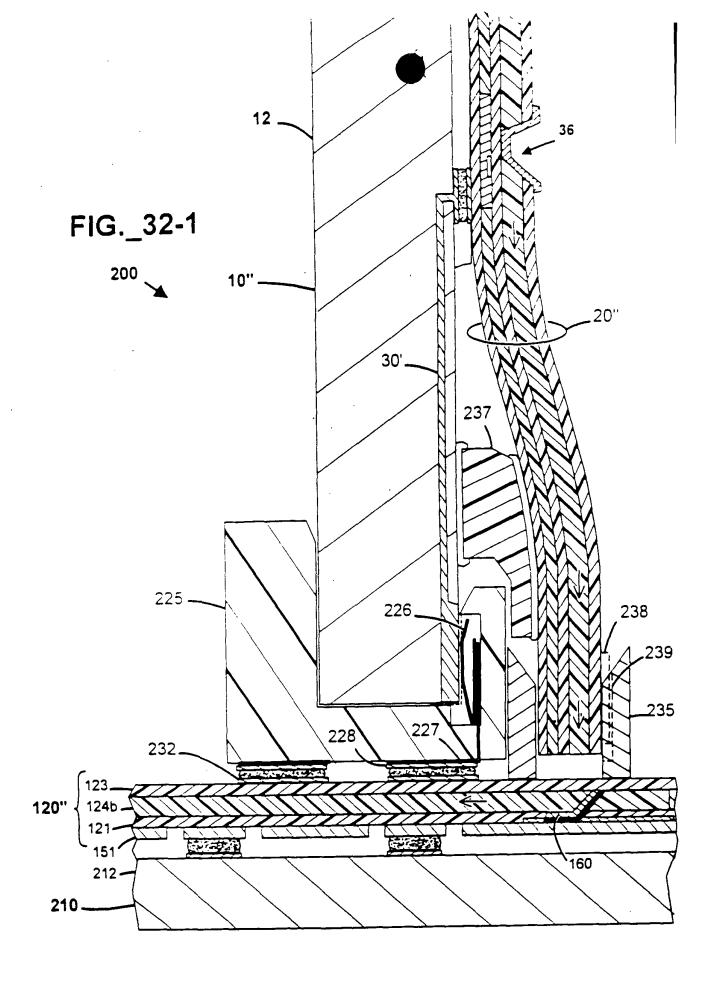


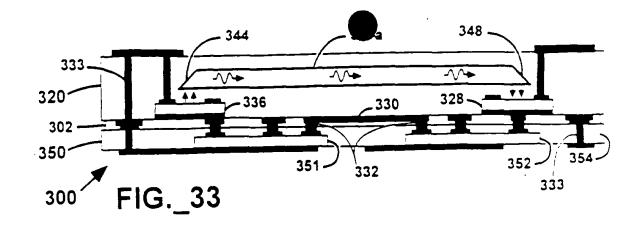


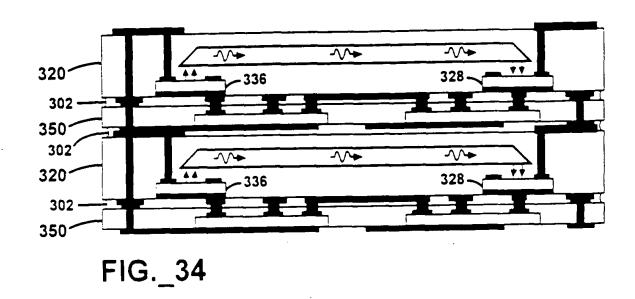


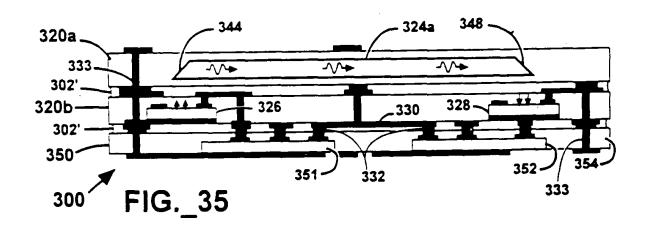












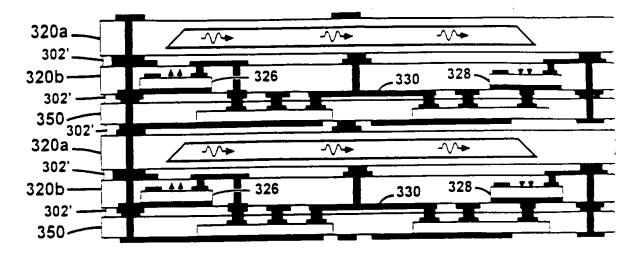
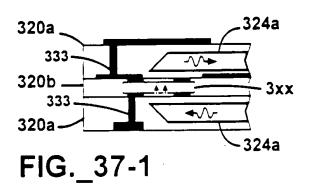
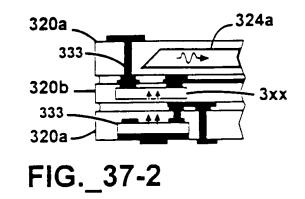
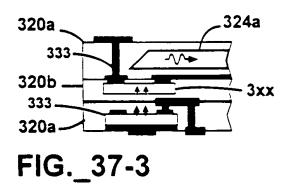
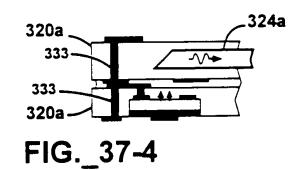


FIG._36









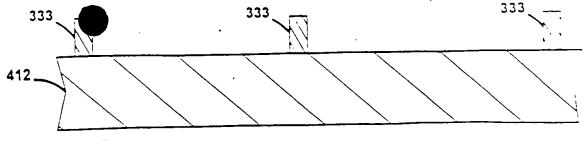


FIG._38

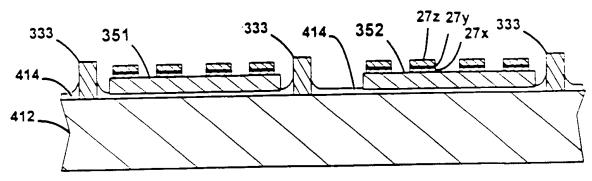


FIG._39

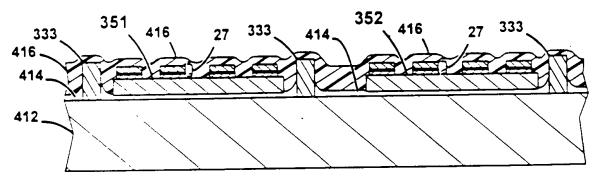


FIG._40

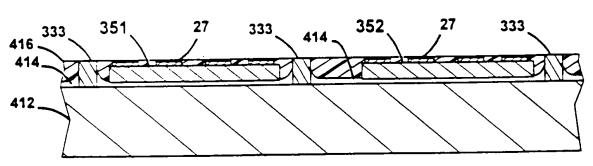


FIG._41

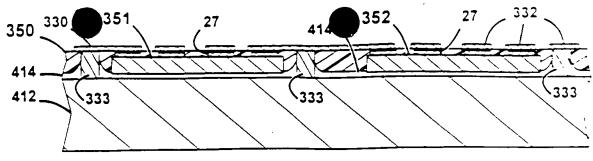


FIG._42

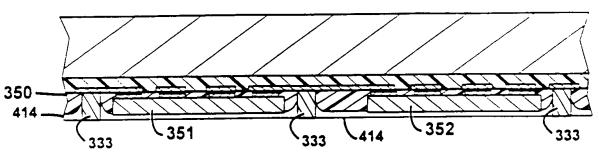


FIG._43

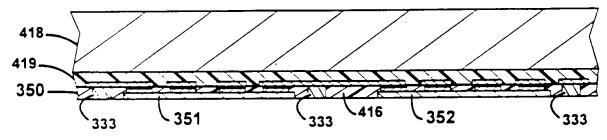


FIG._44

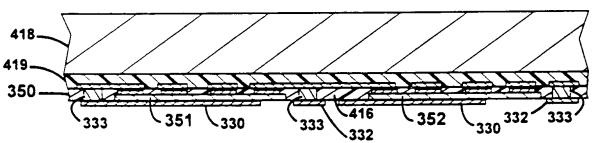
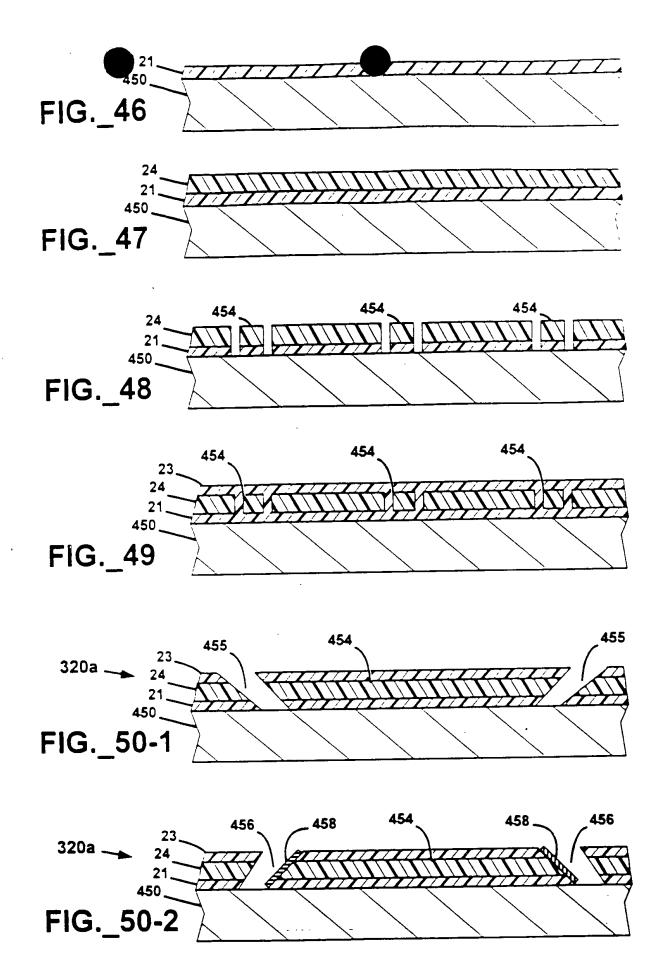
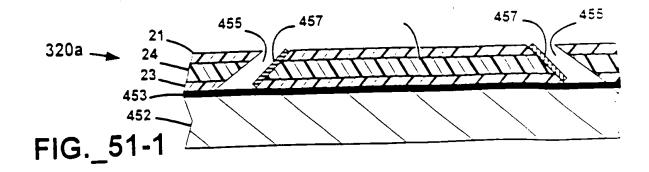
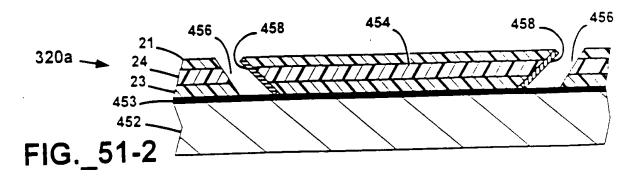
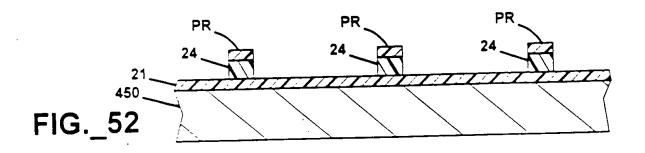


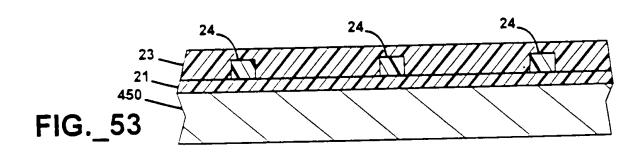
FIG._45

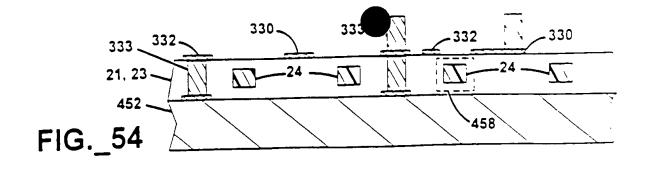


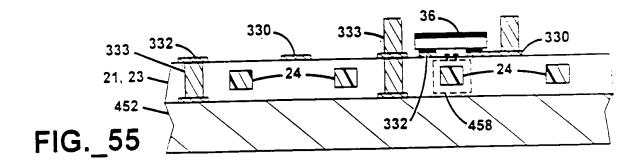


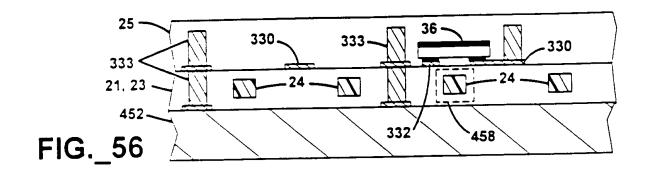


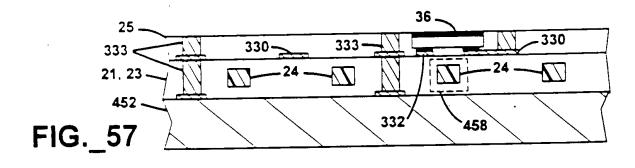


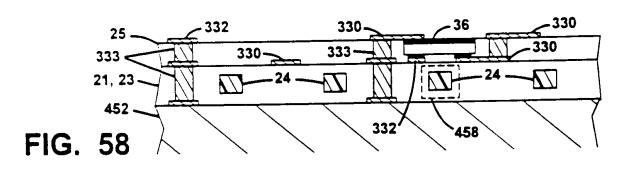


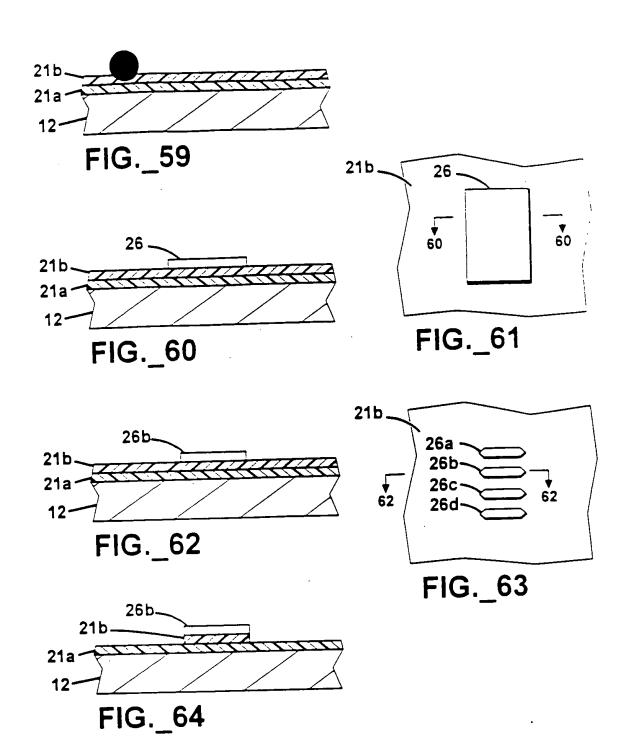


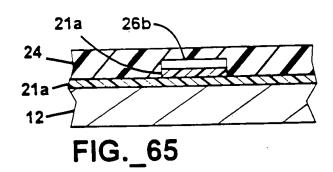


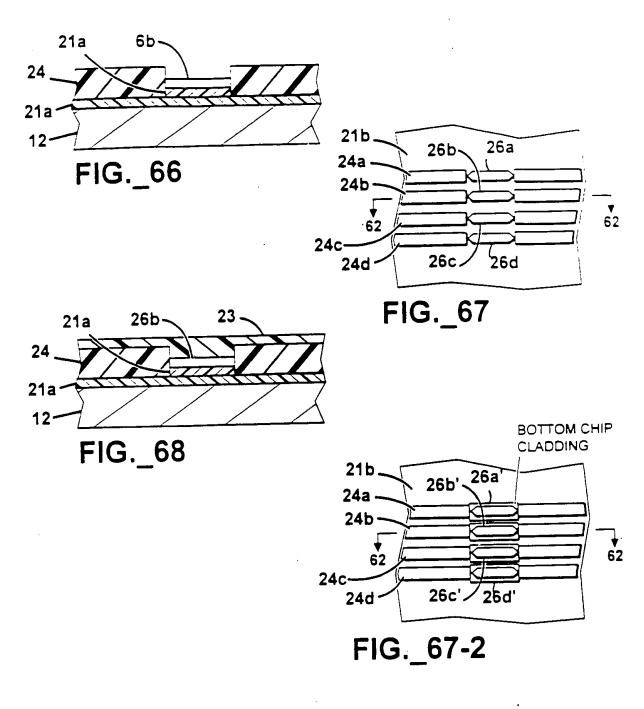


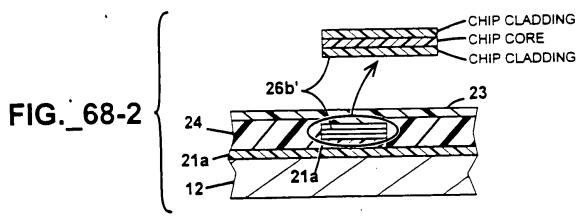


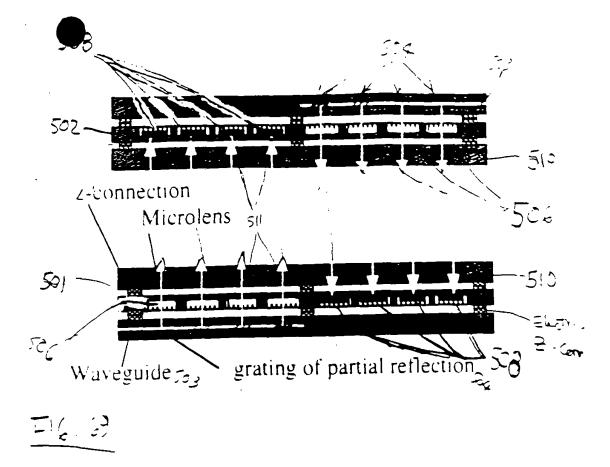


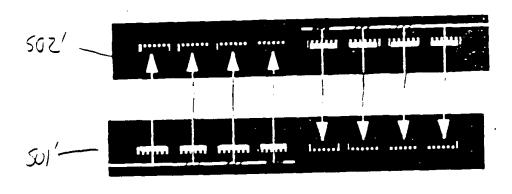




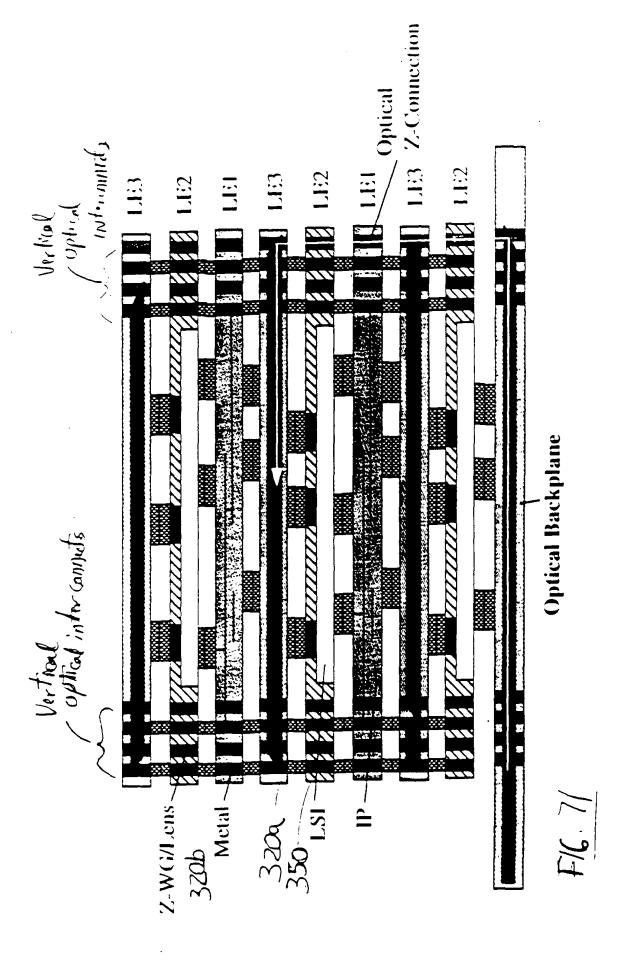


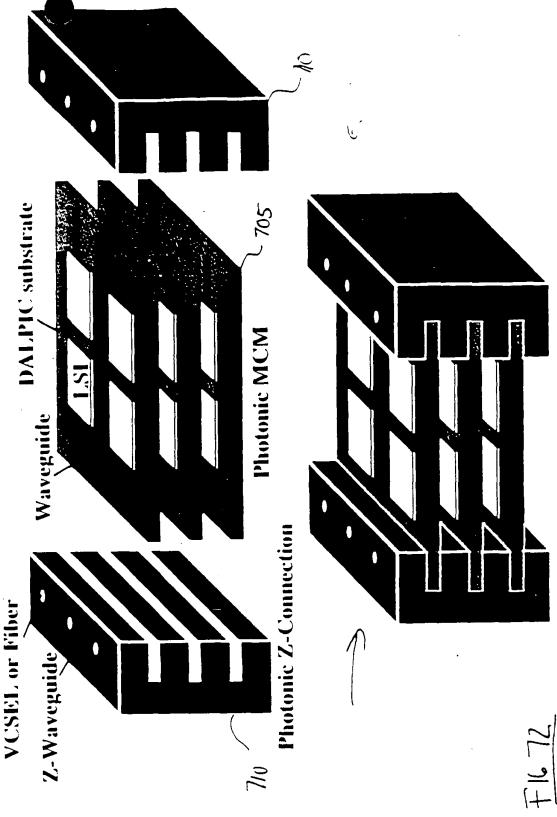


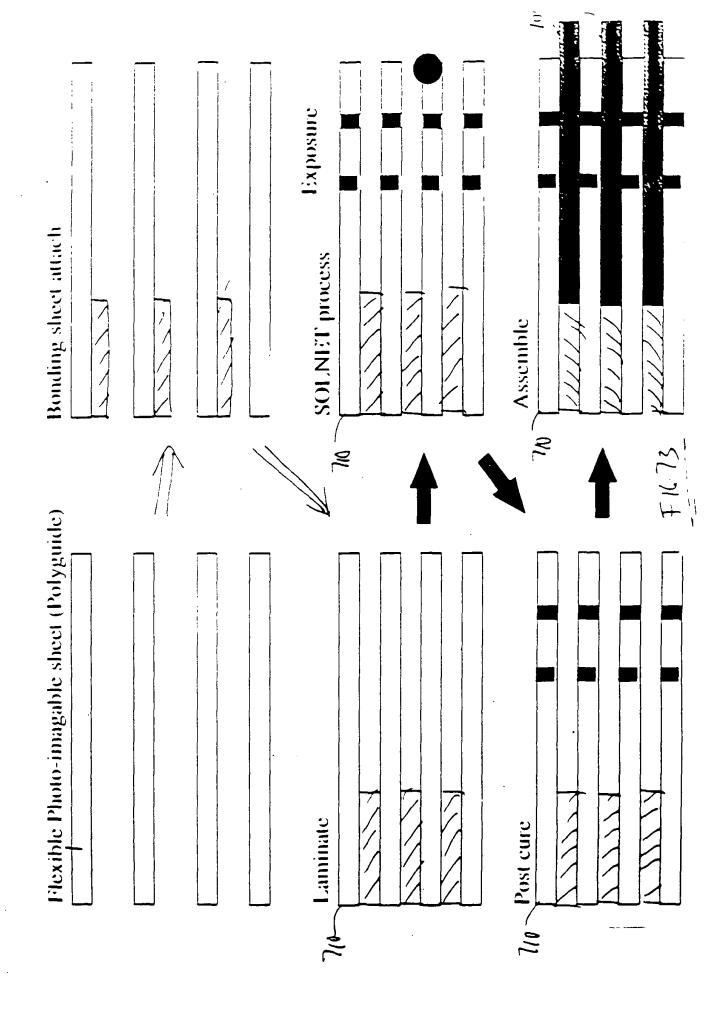




F16. 70







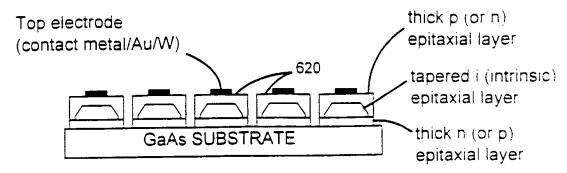
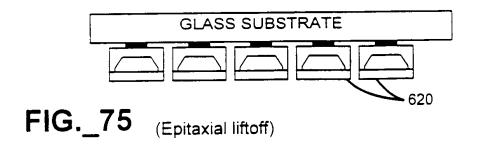


FIG._74 (Epitaxial growth and patterning)



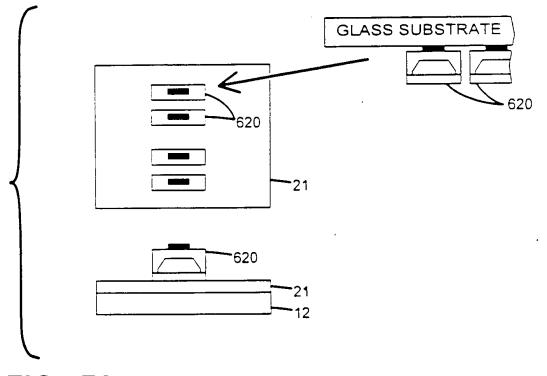
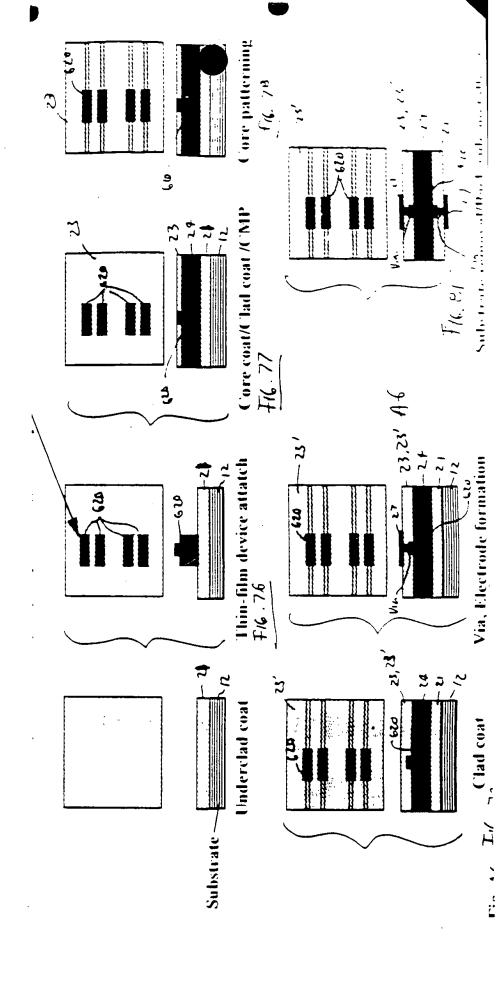
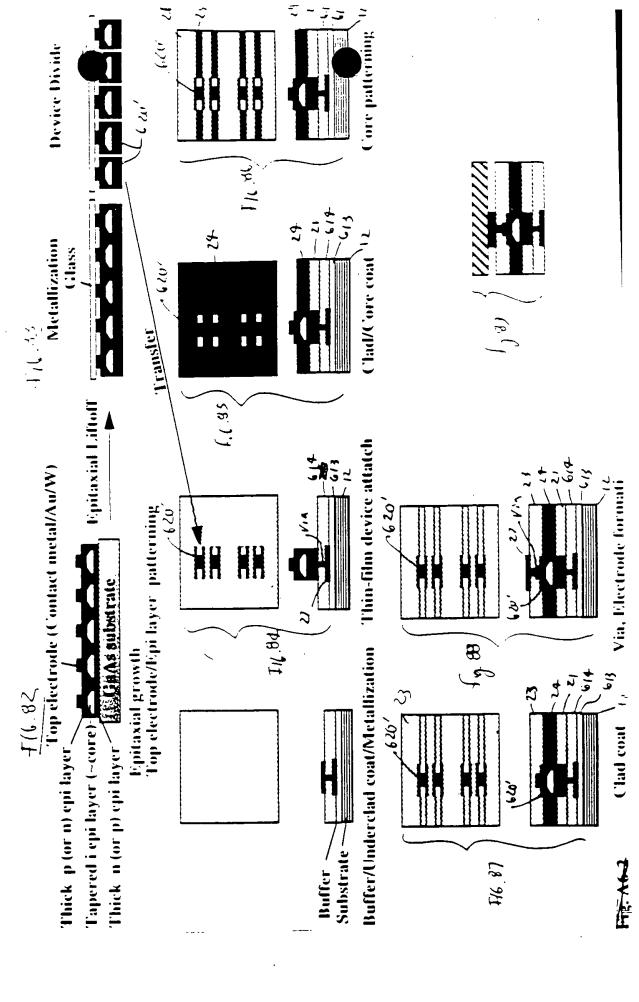
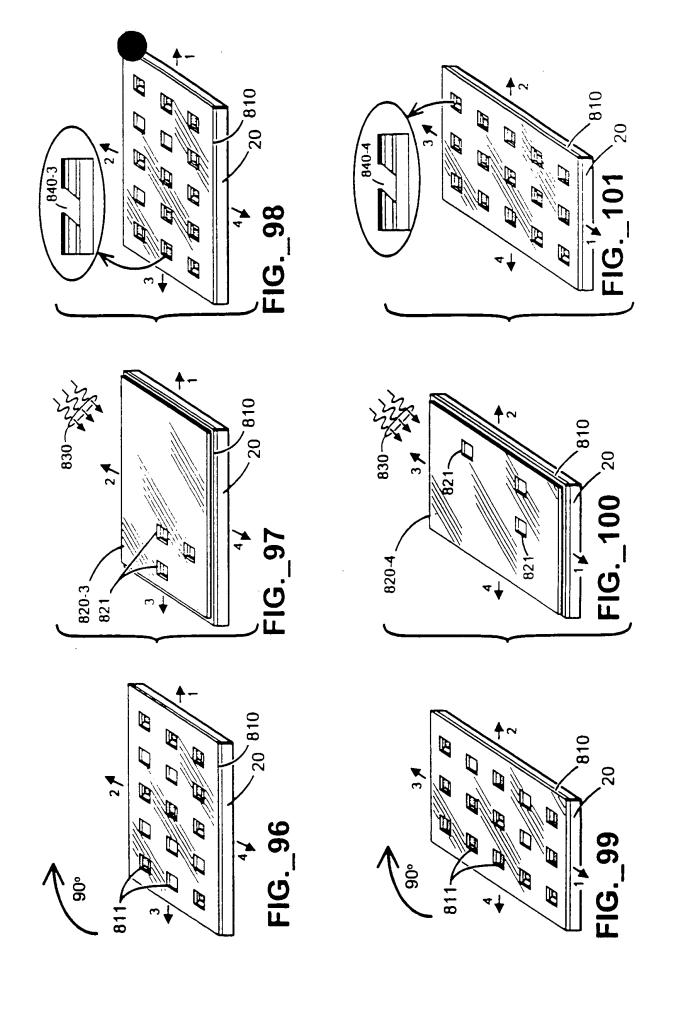
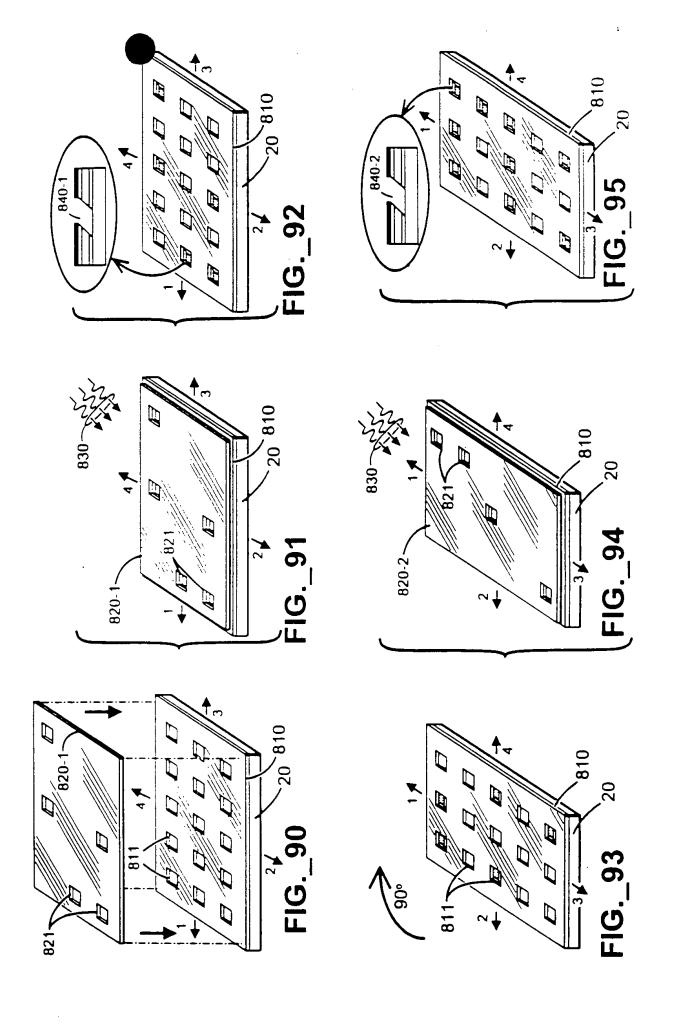


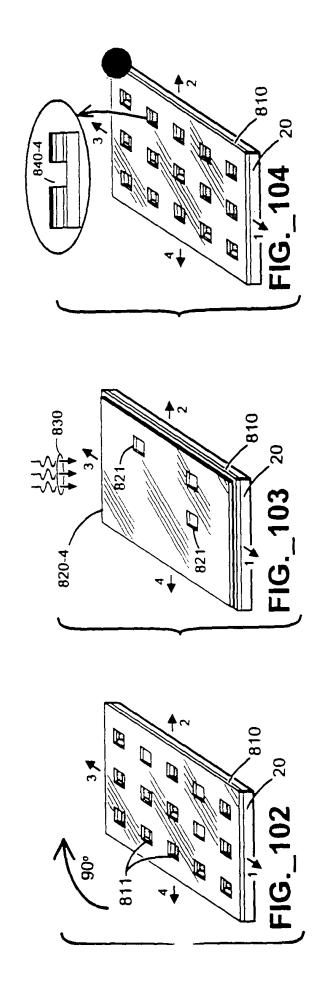
FIG._76 (Transfer)

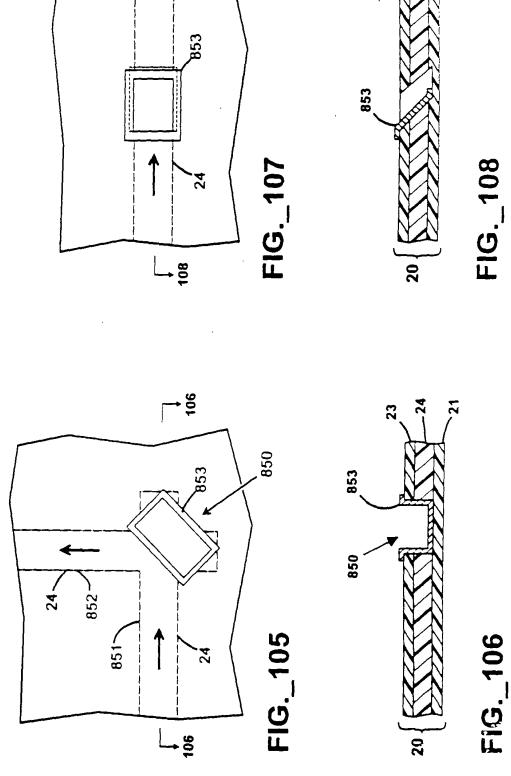








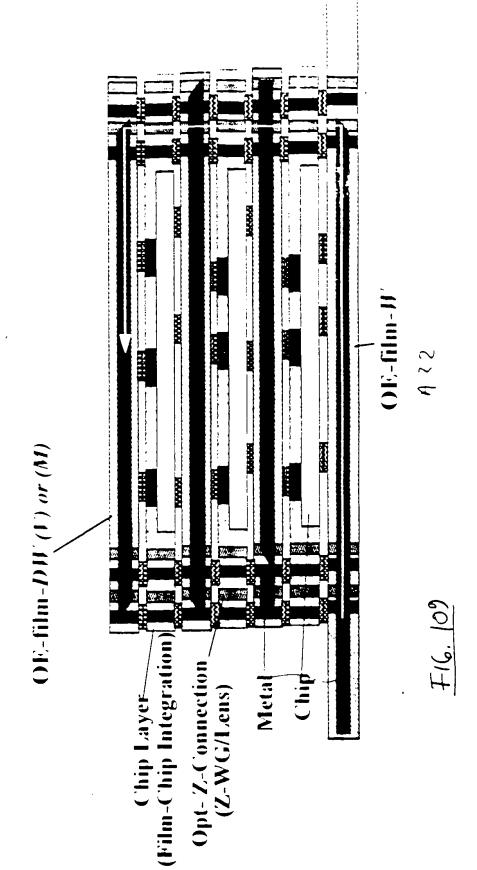


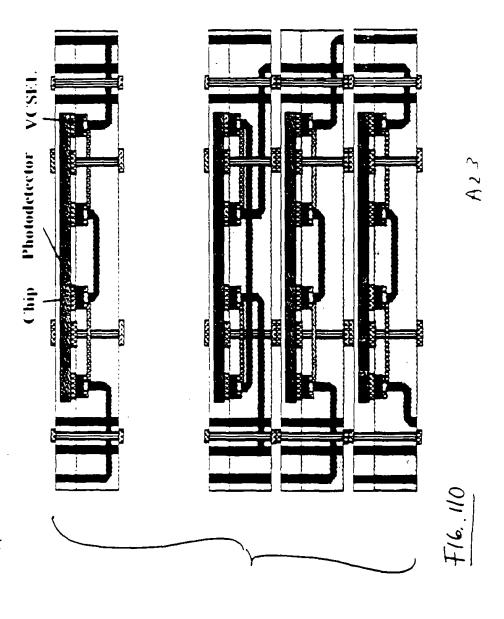


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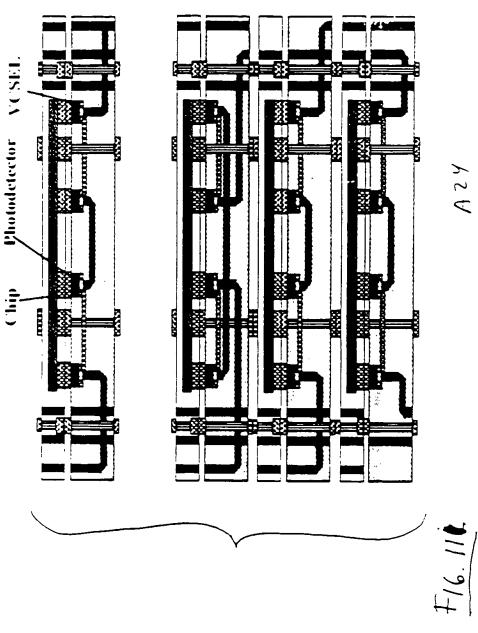
GS CX/CXX OE Solution --- OE-3D-Stack





(2/23/99) AA1 Detail picture Example for 3D-stack

(New version of the AA1 of 2/5/99)

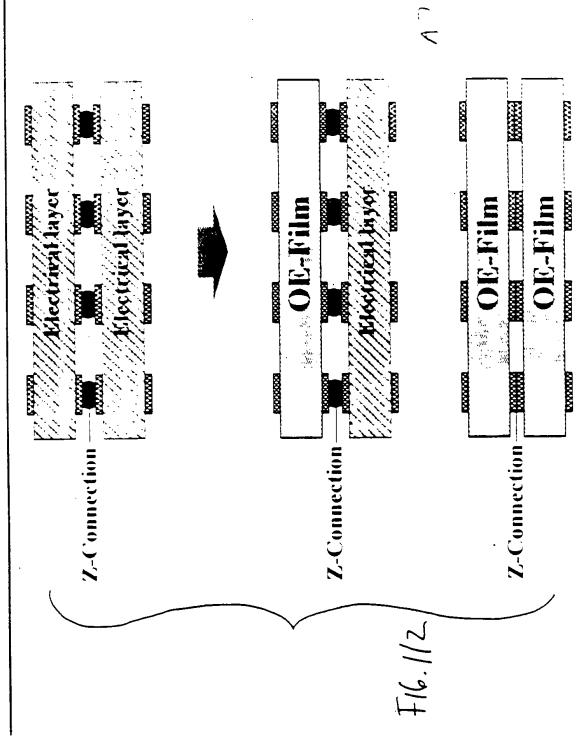


(2/23/99) AA2 Detail picture Example for 3D-stack?

(New version of the AA2 of 2/5/99)

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Film/Z-Connection Application to OE-Substrate

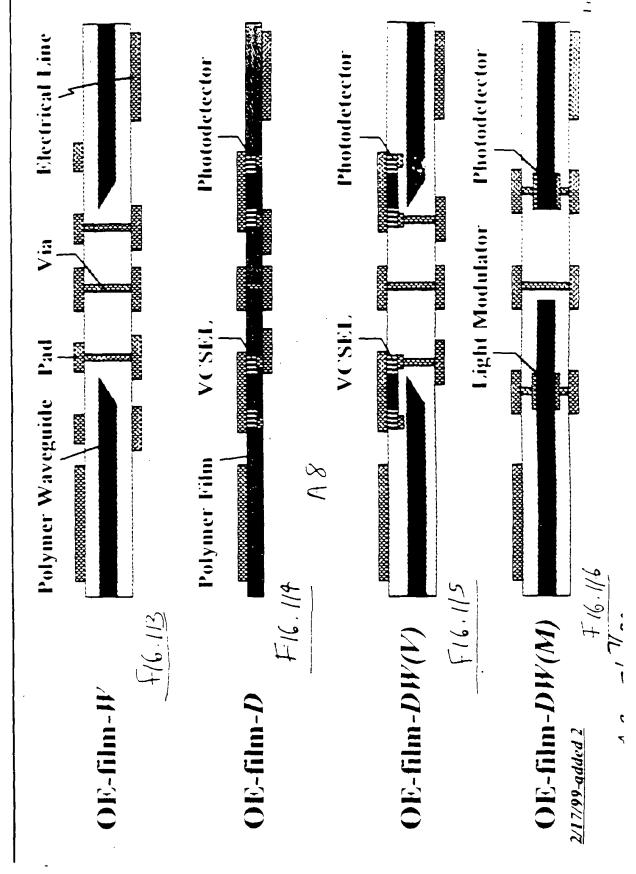


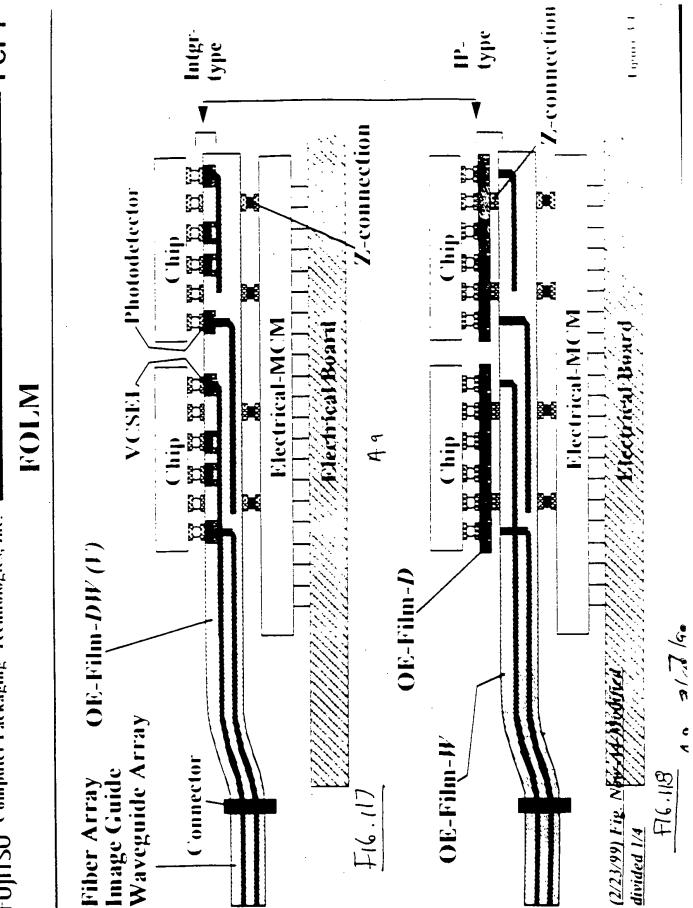
2/23/99-added 1

-

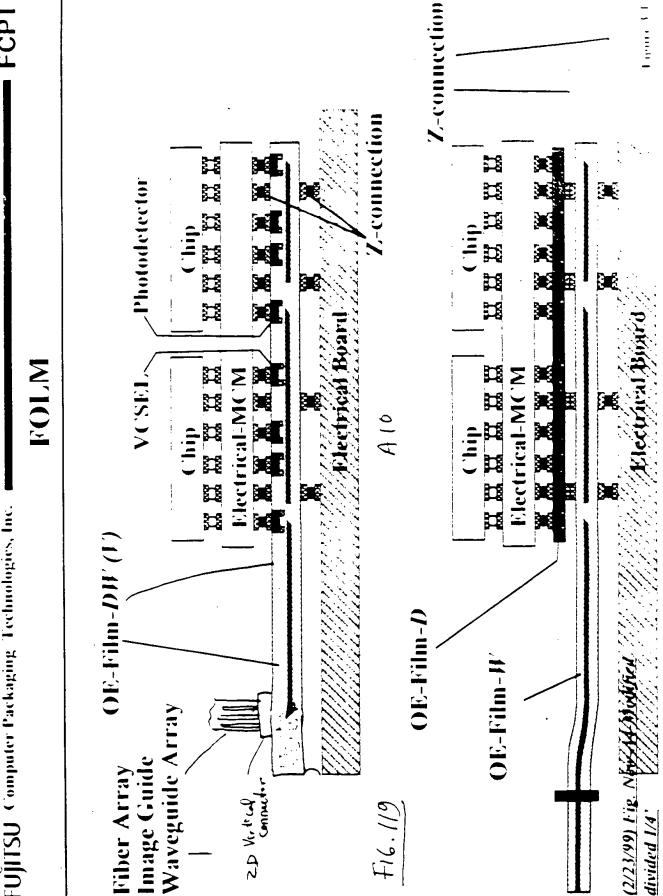
FUJITSU Computer Packaging Technologies, Inc.

OE-Films



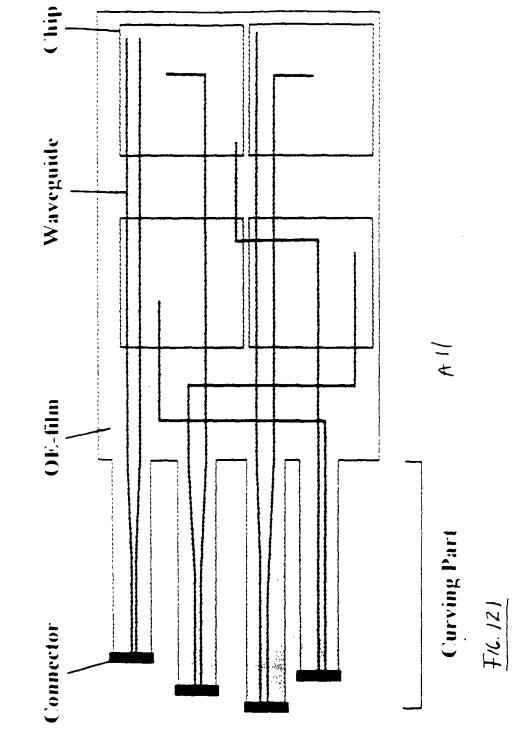


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£16.₩120

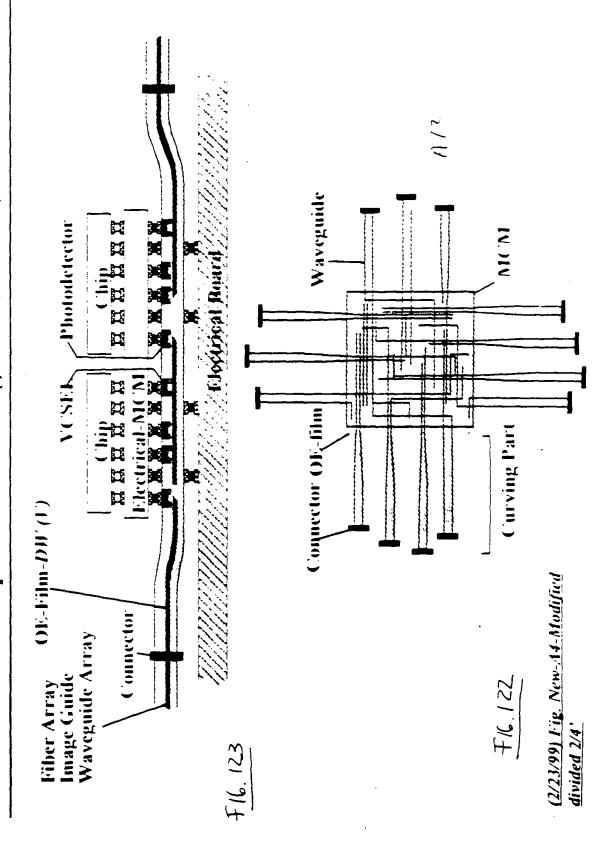
FOLM with Optical Path Length Controller, Connector Buffer FUNTSU Computer Packaging Technologies, Inc. 1



(2/17/99) Fig. New-A4-Modified divided 2/4

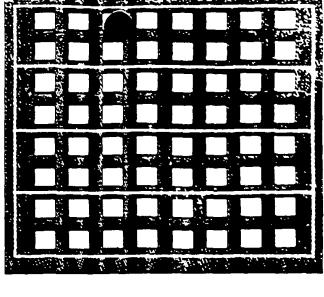
Limited 5.2

FCPT FOLM with Optical Path Length Controller, Connector Buffer FUMTSU Computer Packaging Technologies, Inc.



FOLM with 2D Waveguide Connector FUJITSU Computer Packaging Technologies, Inc.

2D Connector cross-section FOLN A 13 Curving part



(2/23/99) Fig. New-44-Modified divided 3/41

core

F16.129

(for Single-layer waveguide) (for 2 layer waveguide) temo to

FCPT

FUNTSU Computer Packaging Technologies, Inc.

FOLM: High-Speed Option

External Light Z-Connection Light Modulator Chip (MCM, CSP) OE-film-DW(M) **Photodetector** Array Waveguide **Fiber Ribbon** Image guide Connector

F16.125

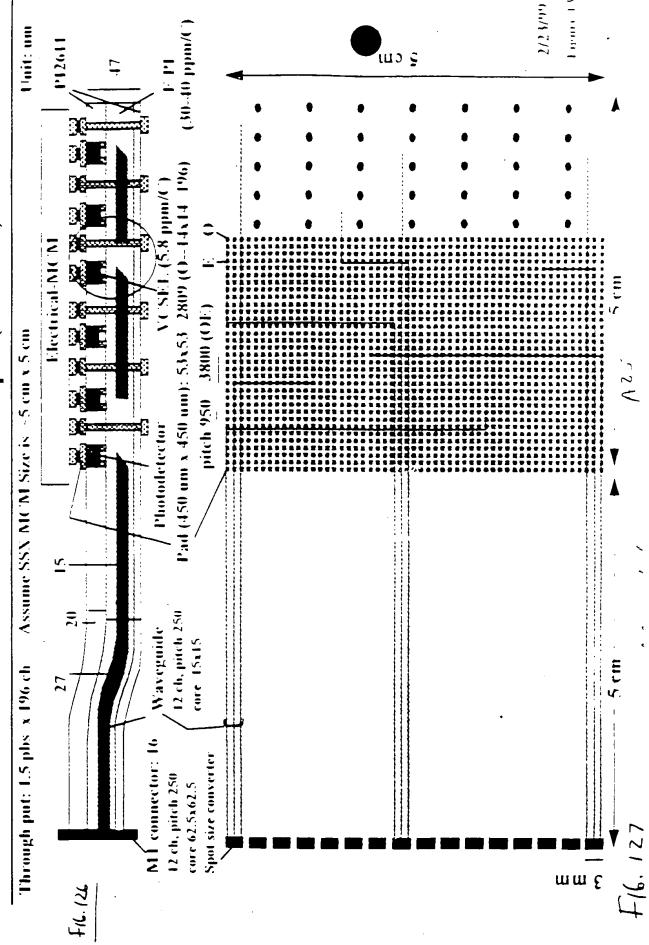
414

(2/17/99) Fig. New-A4-Modified divided 4/4

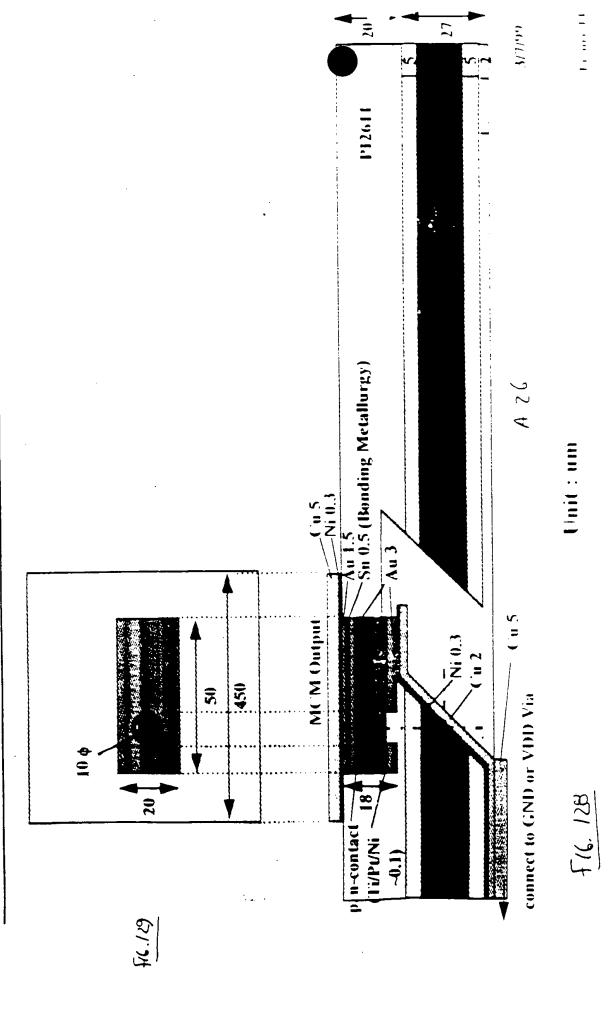
FCPT

FUNTSU Computer Packaging Technologies, Inc.

FOLM Structure Example (Overall)

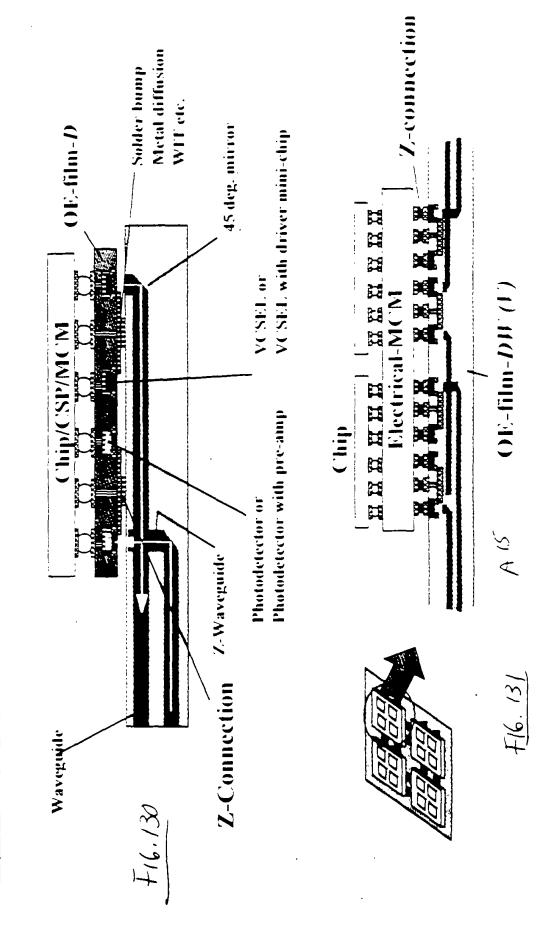


FOLM Structure Example (VCSEL part) FUJITSU Computer Packaging Technologies, Inc.



FUJITSU Computer Packaging Technologies, Inc.

OE-film: OE-IP, OE-Film-MCM

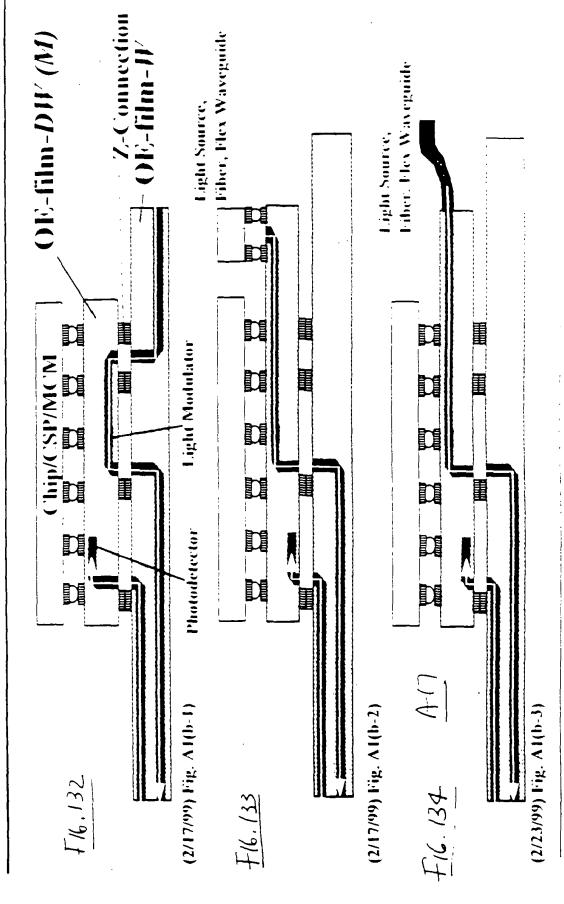


(2/23/99) Fig. New-A1-Modified"

(51 11) - 10/12 71A

1 11.111

OE-film: Light Modulator Transmitters FUJISU Computer Packaging Technologies, Inc. 1



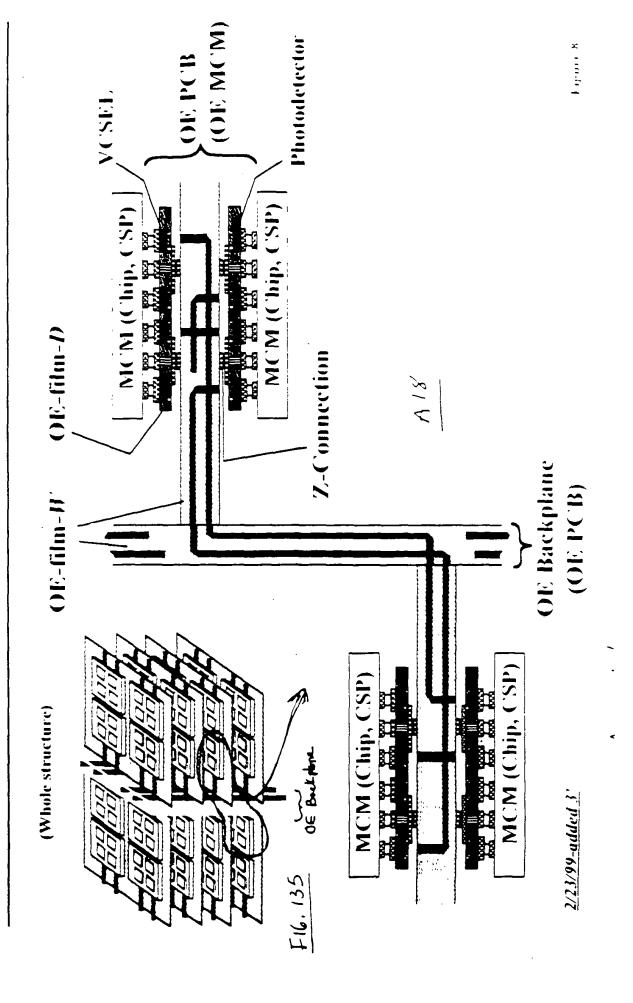
Examples of Light Modulators: Electro-Optic (E.O.) Modulator, Electro Absorption (E.A.) Modulator

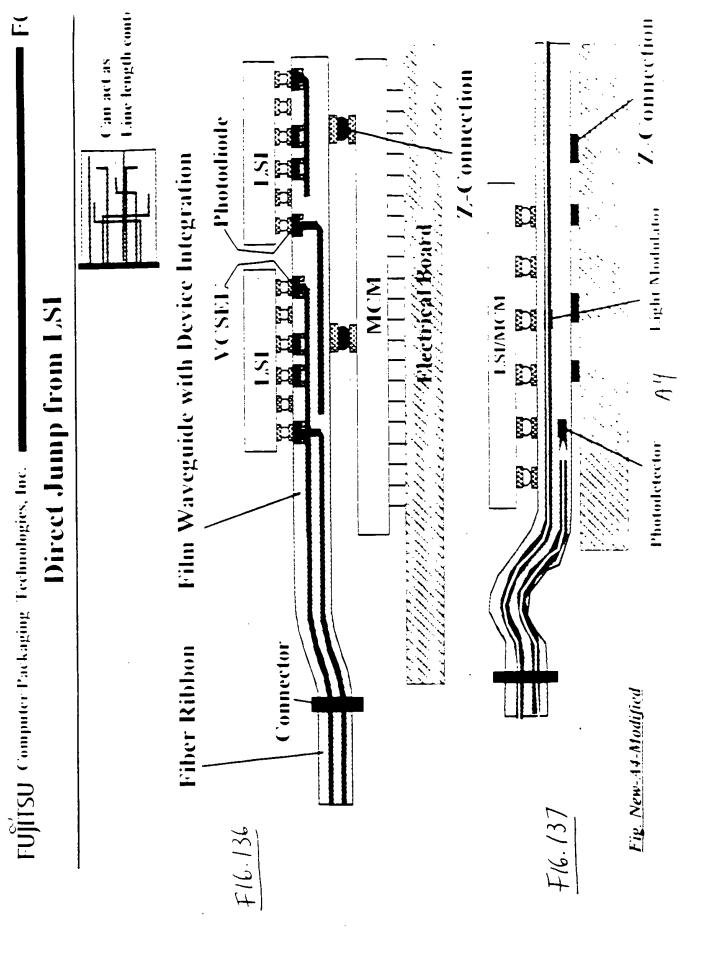
(\ ' \ \)

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FUNTSU Computer Packaging Technologies, Inc.

OE-film: Both-Side Packaging

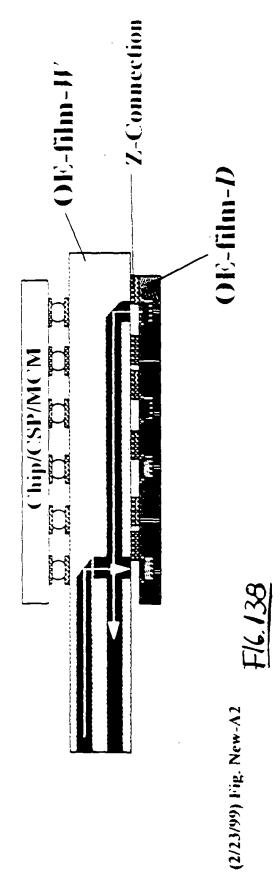




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OE IP is Placed on the Oposit Side



A 20

1-6.

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OE MCM

FCFT

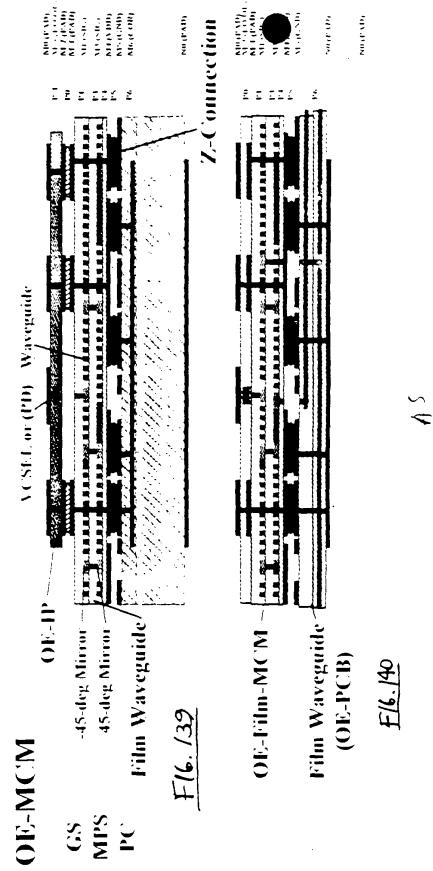
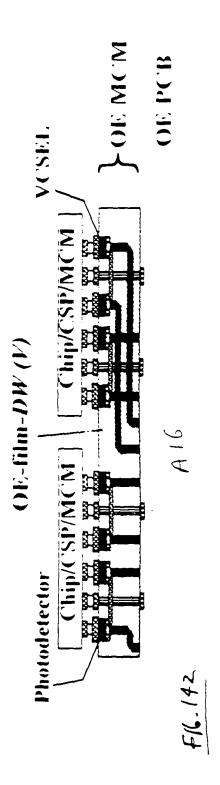


Fig. A5-Modifice

OE-film: Smart Pixel

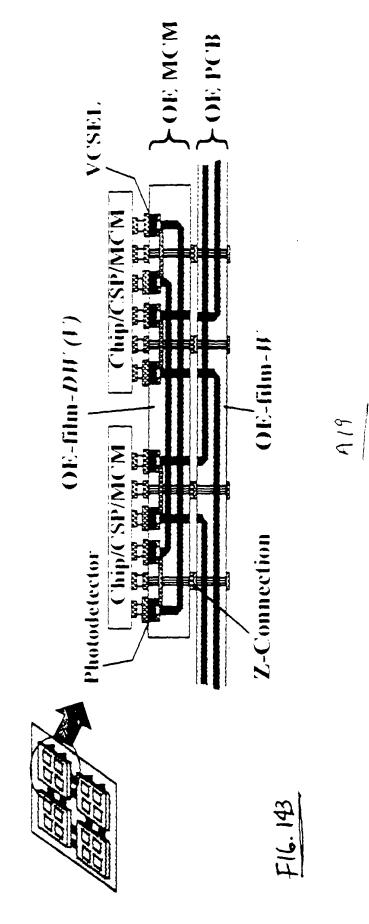


F16. 141



OE-Film/OE-Film Stack --- Back-Side Connection 1 Of 150 vomputer Fackaging Technologies, Inc. 1

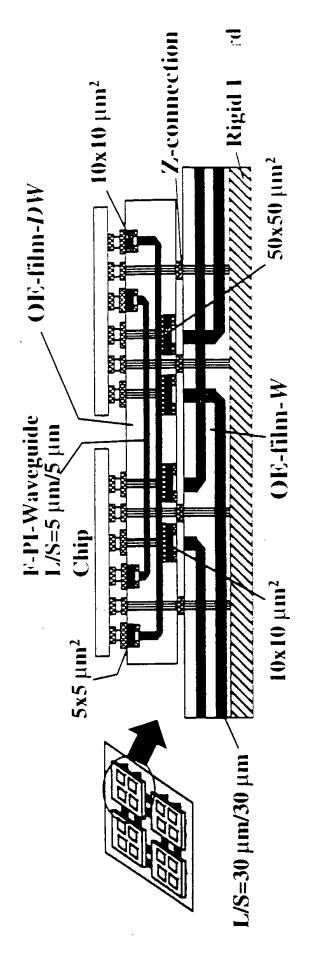
FCF



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A19 21-100

OE-Film/OE-Film Stack --- Back-Side Connection FUNTSU Computer Packaging Technologies, Inc.



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F16, 144

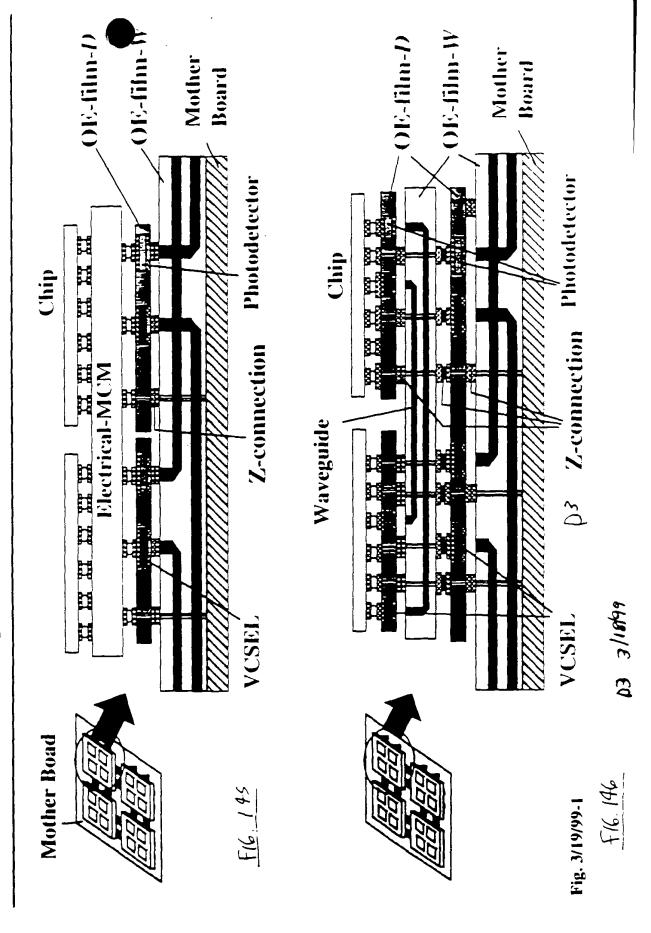
3/7

Fig. 3/18/99-1 01 3/18/99

OE-MCM/OE-Bord Stack

FUITSU Computer Packaging Technologies, Inc.

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[UJITSU] Computer Packaging Technologies, Inc. 1

Device Integration Process



- Thin film devices (2) Placement of
- 16. 193 Course Monney Roman
- [16.149

(3) Polymer coat

16 13 Second .

(4) Planarization

- [16.15] (5) Vias/Pads/Lines formation
- 781911

¬▼ (6) Substrate removat

- OE-film-D
- → (6*) Jump to the waveguide formation process

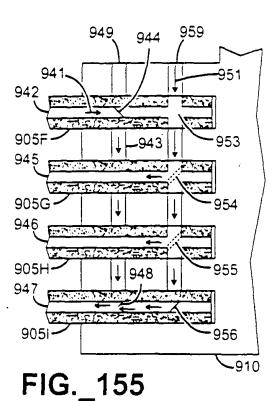


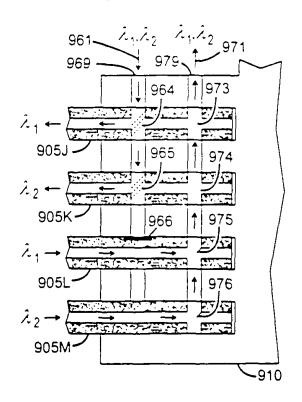
OE-film-DH(1)

DOVERS DIESSI

FIG.__154



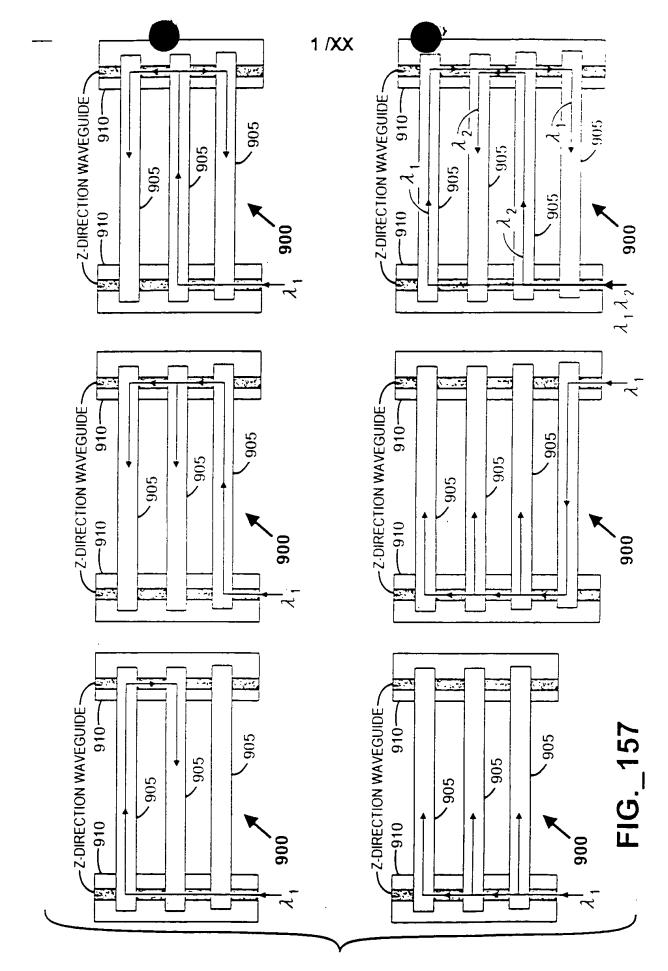


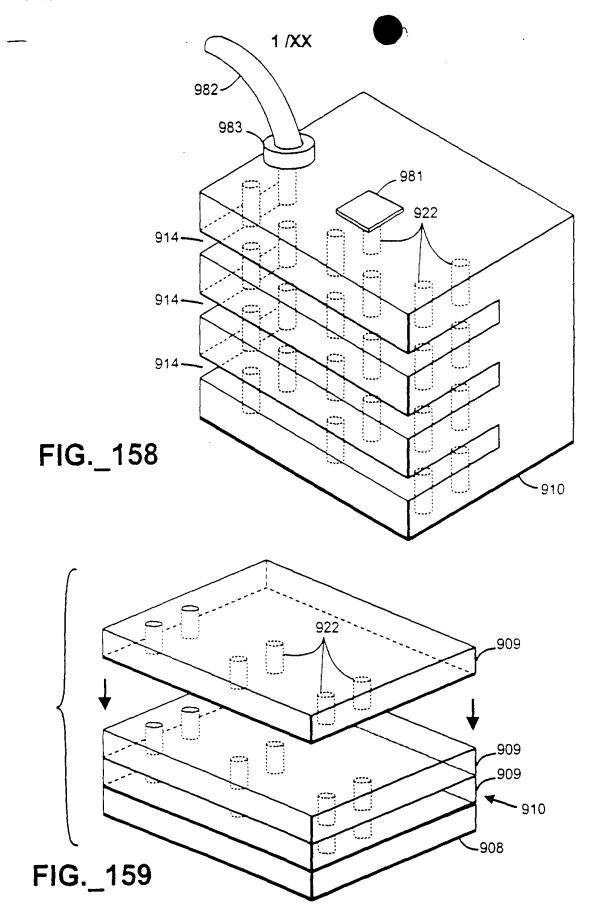


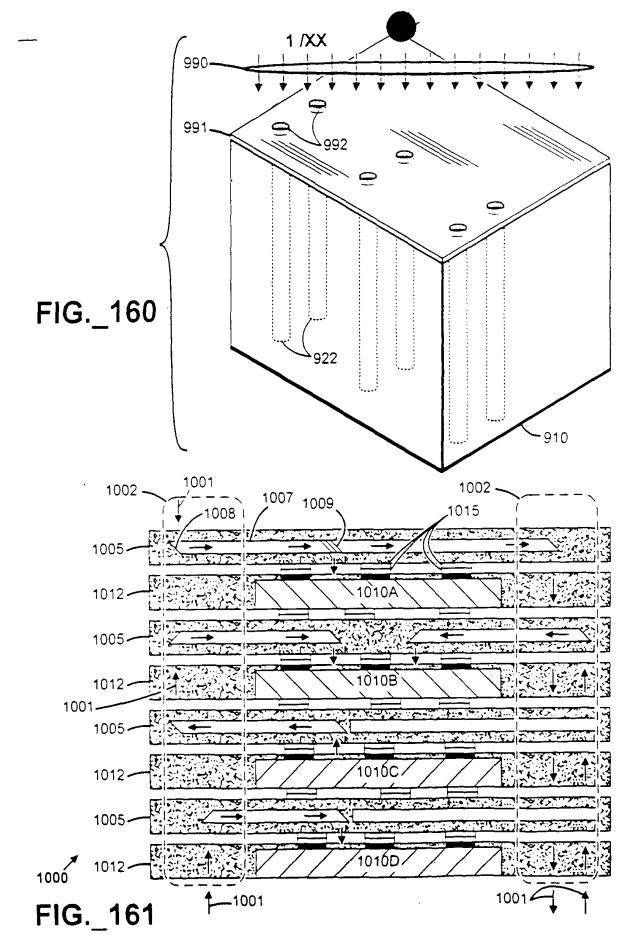
961' 979' 971' 969' 979' 971' 965' λ_1, λ_2 9050 966 966 966 λ_1, λ_2 9050 λ_1, λ_2 9050 λ_1, λ_2 9050 λ_1, λ_2 9050 λ_1, λ_2 910

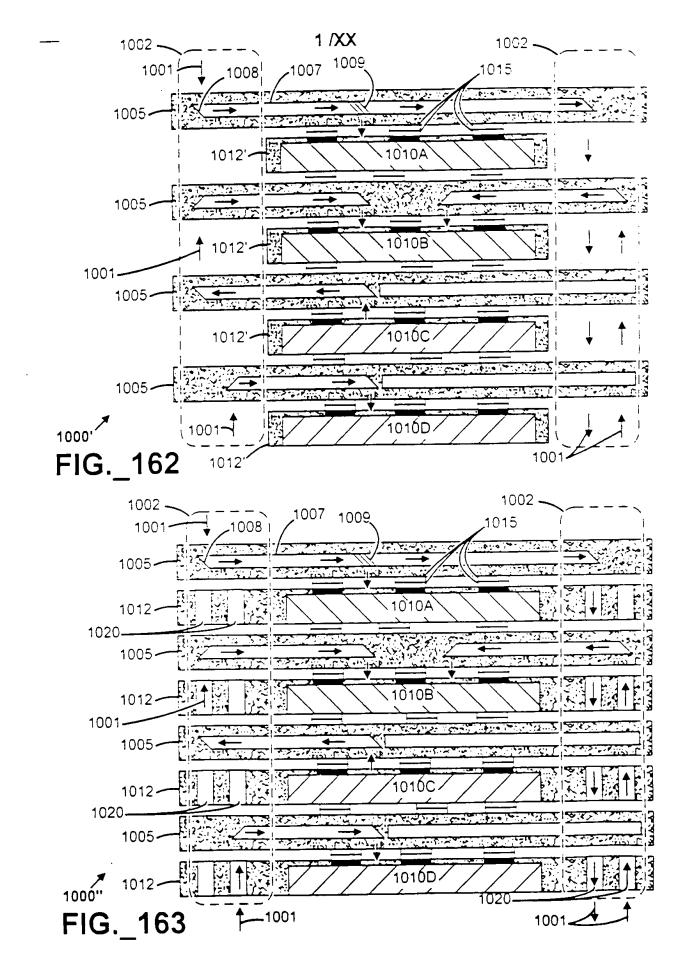
FIG._156-1

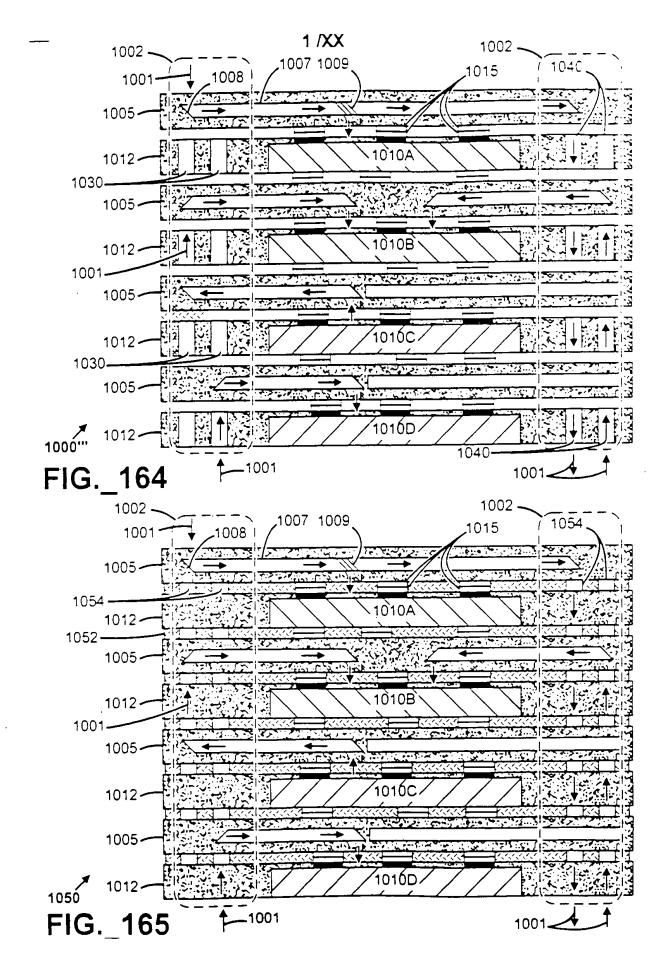
FIG._156-2

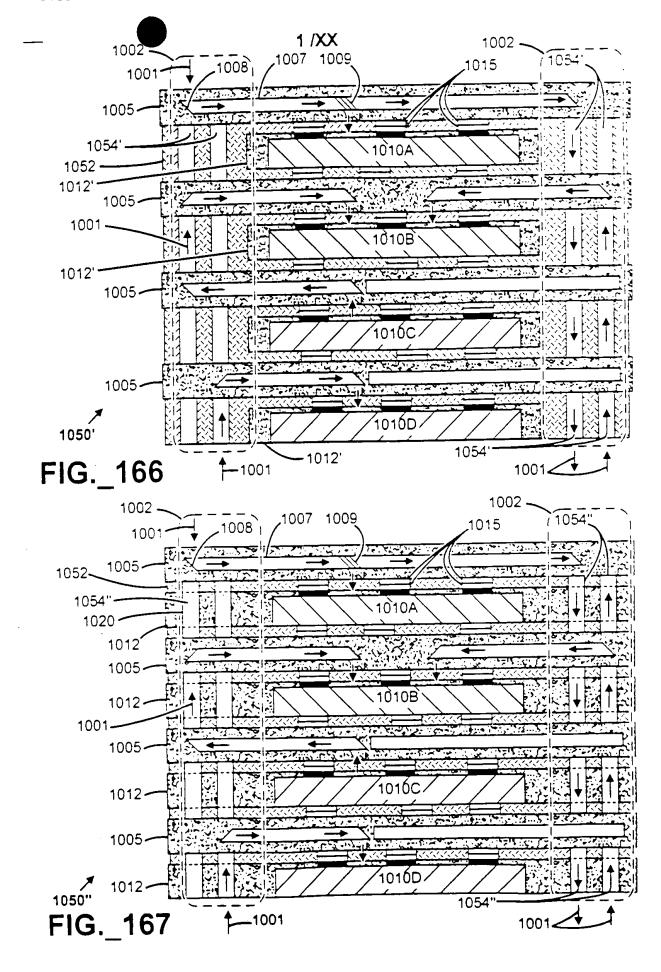


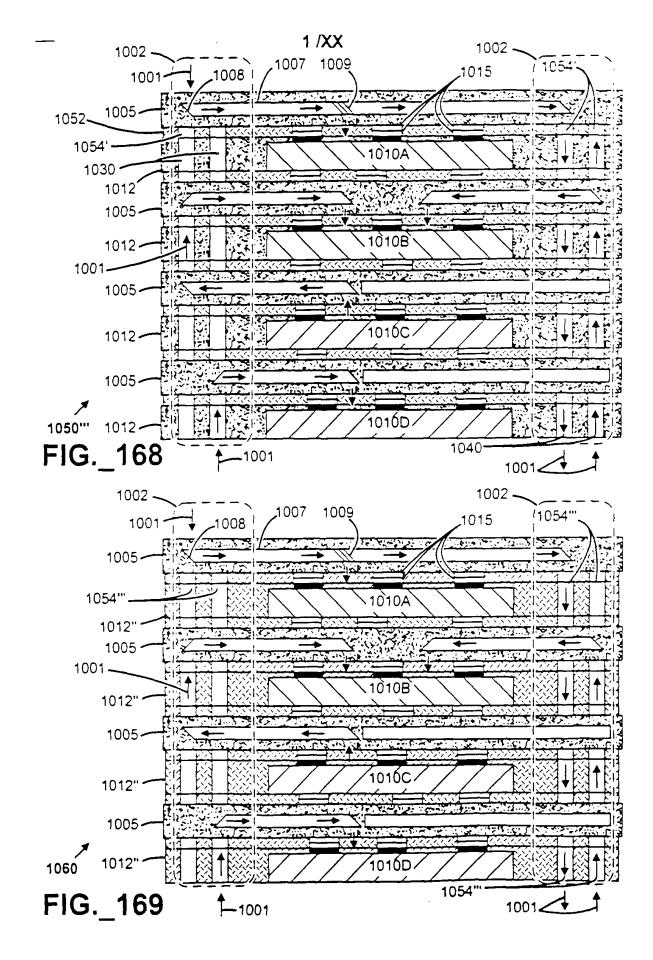












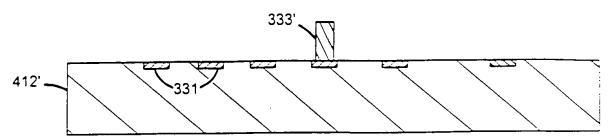


FIG._170

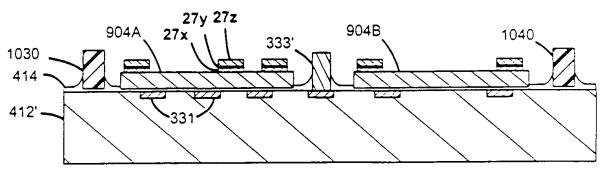


FIG._171

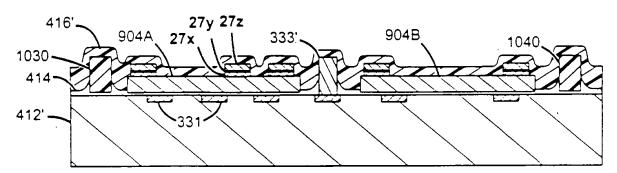


FIG._172

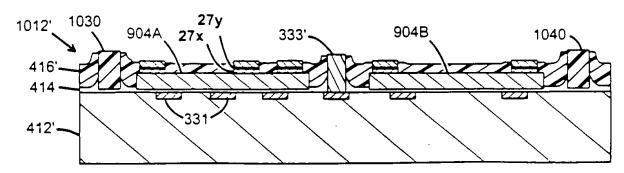


FIG._173

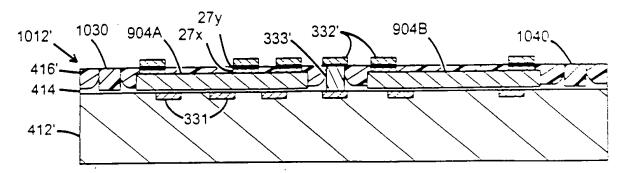


FIG._174

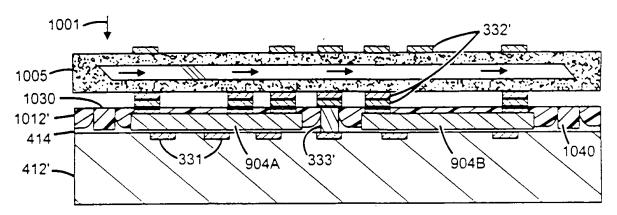
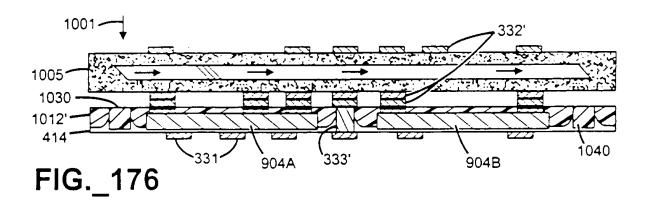


FIG._175



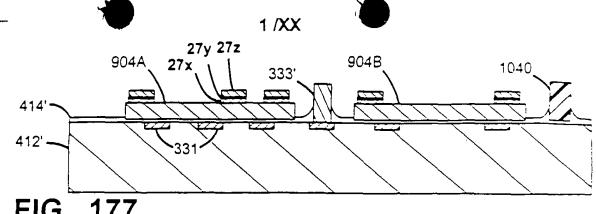


FIG._177

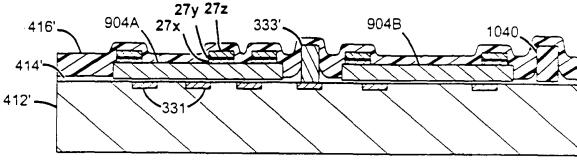


FIG._178

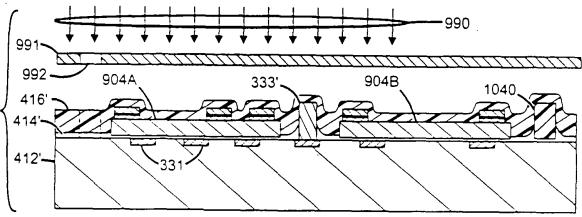


FIG._179

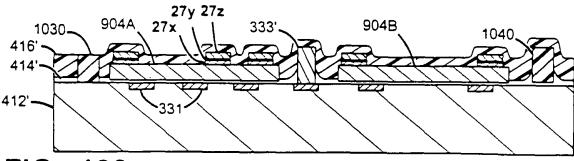
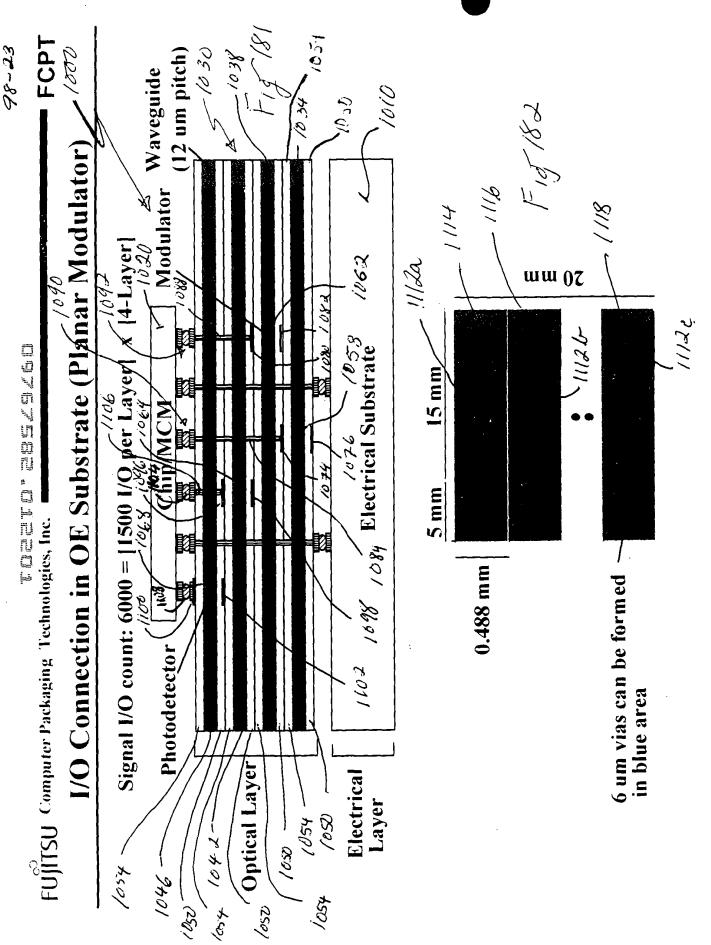
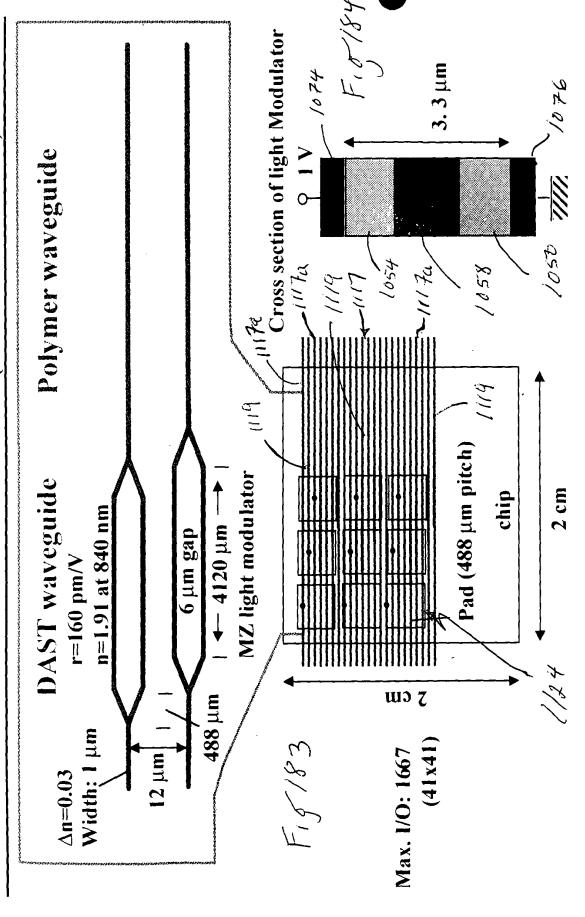


FIG._180



I/O Connection in OE Substrate (Planar Modulator)

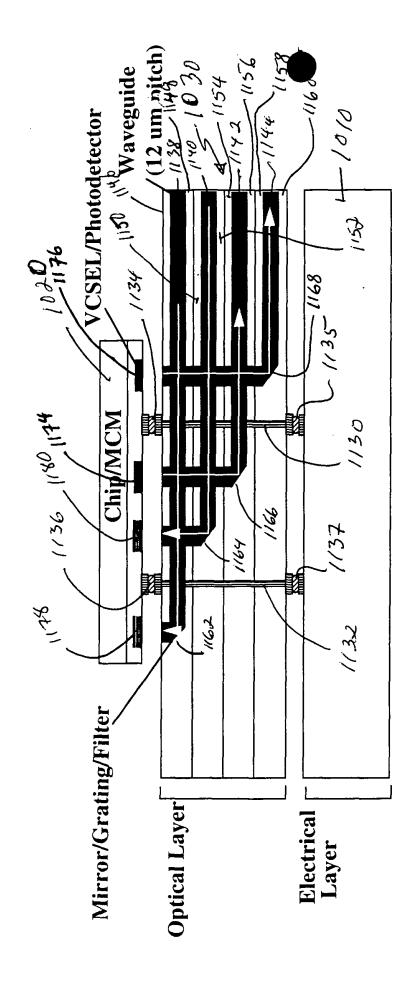


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I/O Connection in OE Substrate (OE-VLSI)

Signal I/O count: $6000 = [1500 \text{ I/O per Layer}] \times [4-\text{Layer}]$



F19 185

FCPT

FUJTSU Computer Packaging Technologies, Inc.

I/O Connection in OE Substrate (OE-VLSI)

103 (12 um pitch) , 1154 Waveguide 1142 021-VCSEL/Photodetector 1138) (14 4) (14 4 Signal I/O count: $6000 = [1500 \text{ I/O per Layer}] \times [4-\text{Layer}]$ 84)1 11134 0811 1130 Fig 186 Chip/MCM , 961), 1130C 1130 C. ts/1 9511 1326 1/334 Mirror/Grating/Filter Electrical Optical Layer (della Layer 1200c

Fig.

FUMTSU Computer Packaging Technologies, Inc.

I/O Connection in OE Substrate (OE-VLSI, WDM)

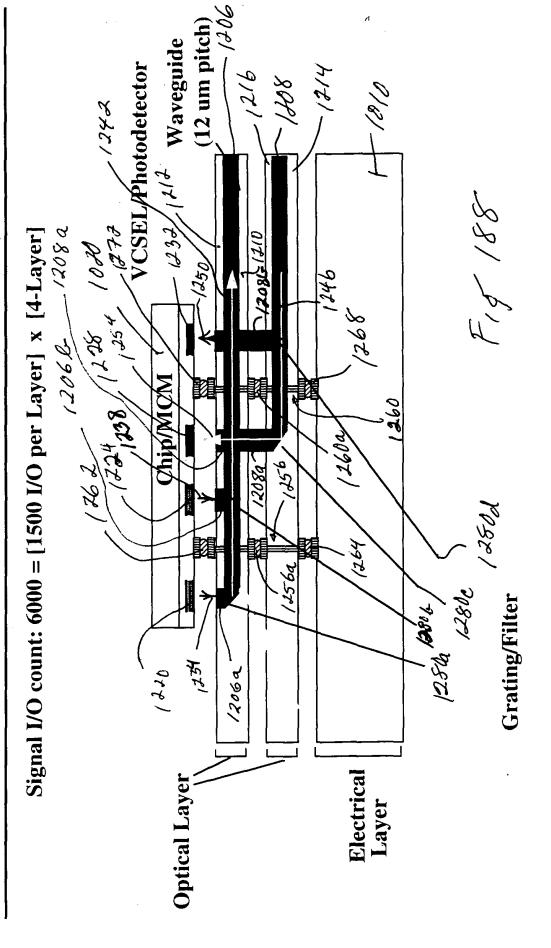
Signal I/O count: $6000 = [1500 \text{ I/O per Layer}] \times [4-\text{Layer}]$

(12 um pitch) -14/2 Waveguide 1208 -1208 VCSEL/Photodetector 1020 1246 1210, CC1 -1243 1 890/ Chip/MCM 73086 1 Jech Grating/Filter 12800° Electrical Layer

FCPT

FUITSU Computer Packaging Technologies, Inc.

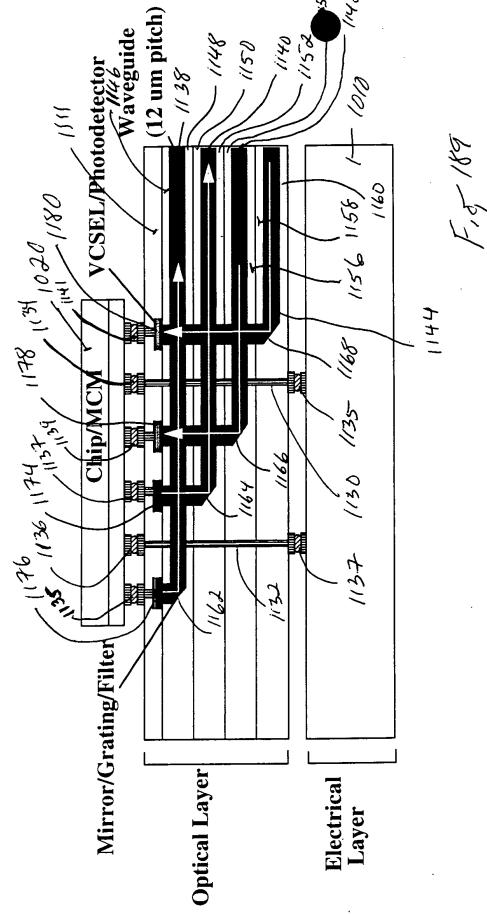
I/O Connection in OE Substrate (OE-VLSI, WDM)



FUITSU Computer Packaging Technologies, Inc.

I/O Connection in OE Substrate (Active OE Layer)

Signal I/O count: $6000 = [1500 \text{ I/O per Layer}] \times [4\text{-Layer}]$



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I/O Connection in OE Substrate (Active OE Layer)

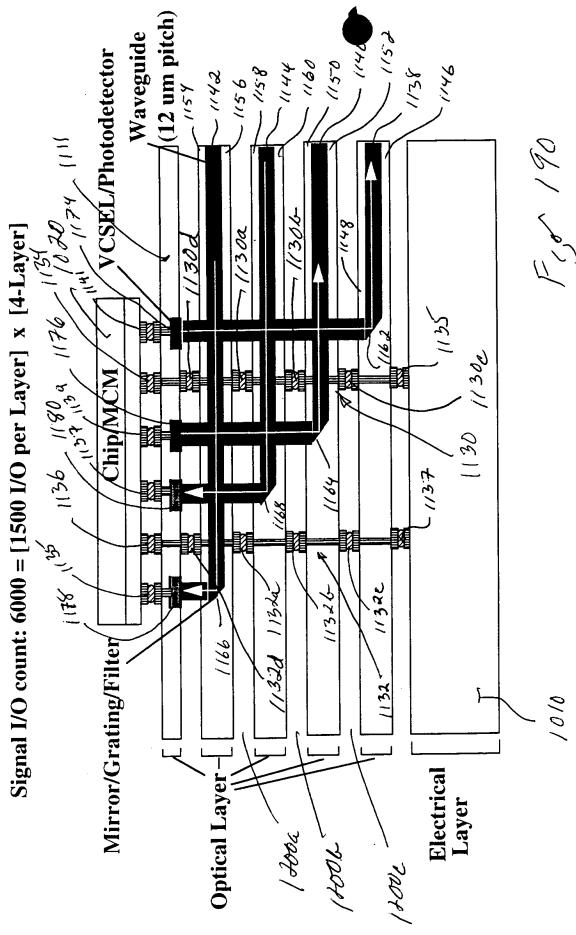


Fig. 9

FUNTSU Computer Packaging Technologies, Inc.

■ FCPT

I/O Connection in OE Substrate (Active OE Layer, WDM)

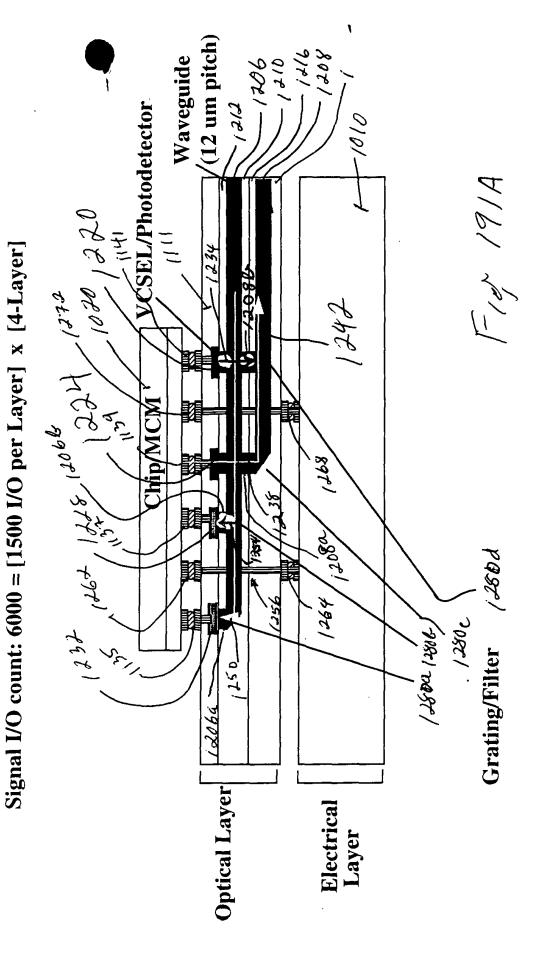
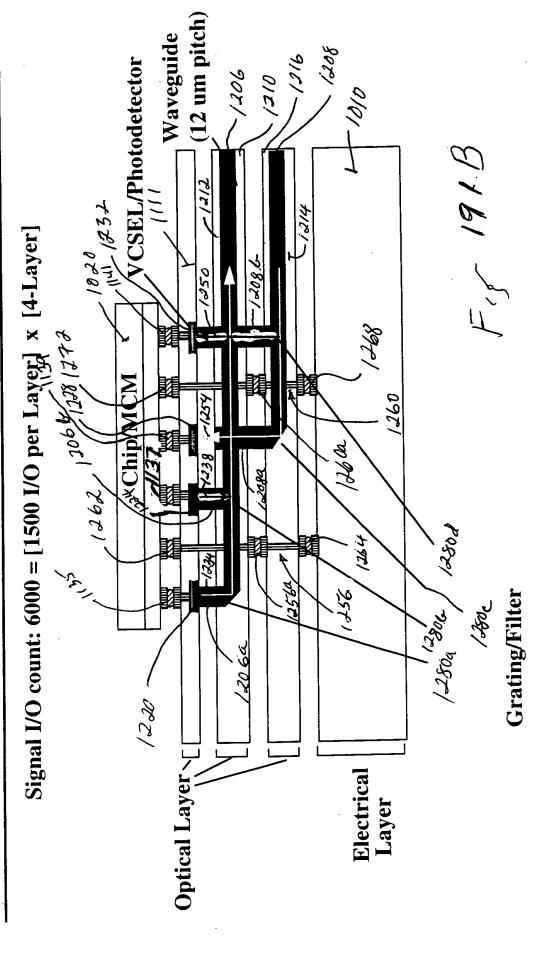


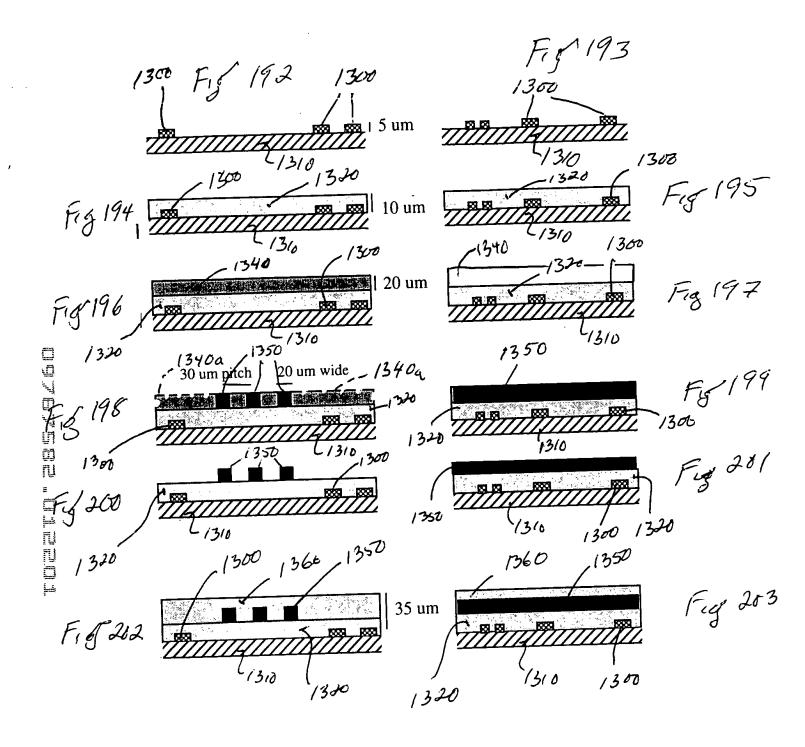
Fig. 10

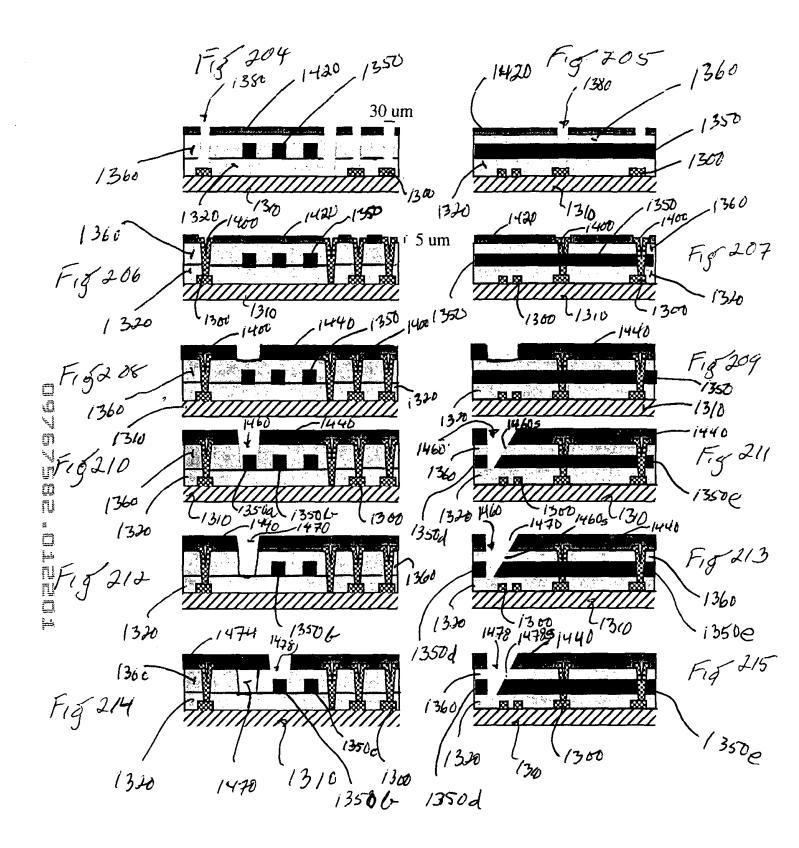
FCP

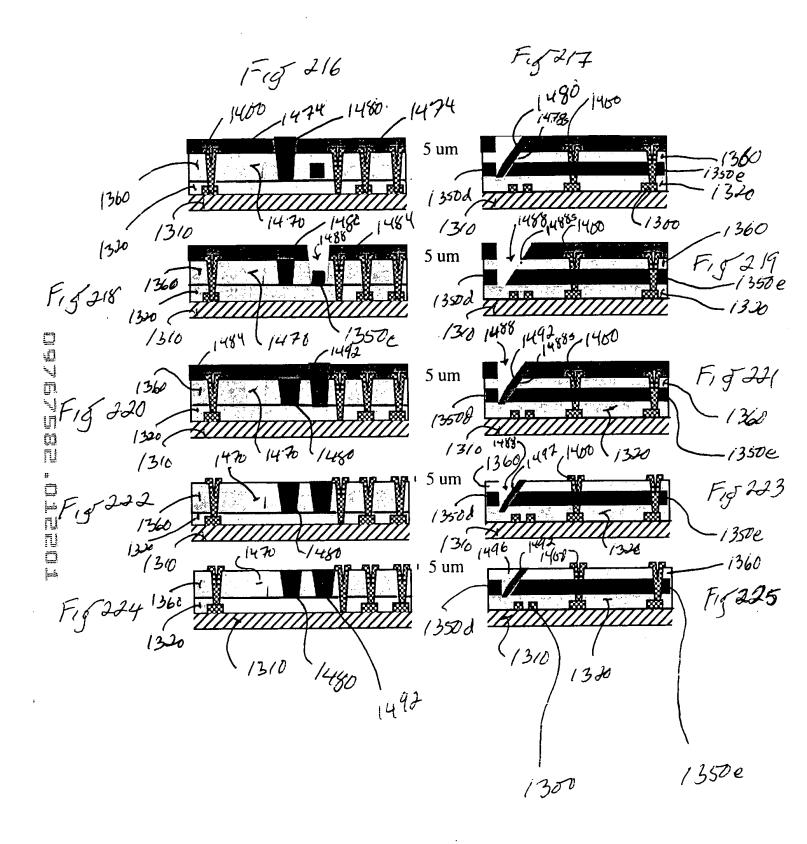
FUNTSU Computer Packaging Technologies, Inc.

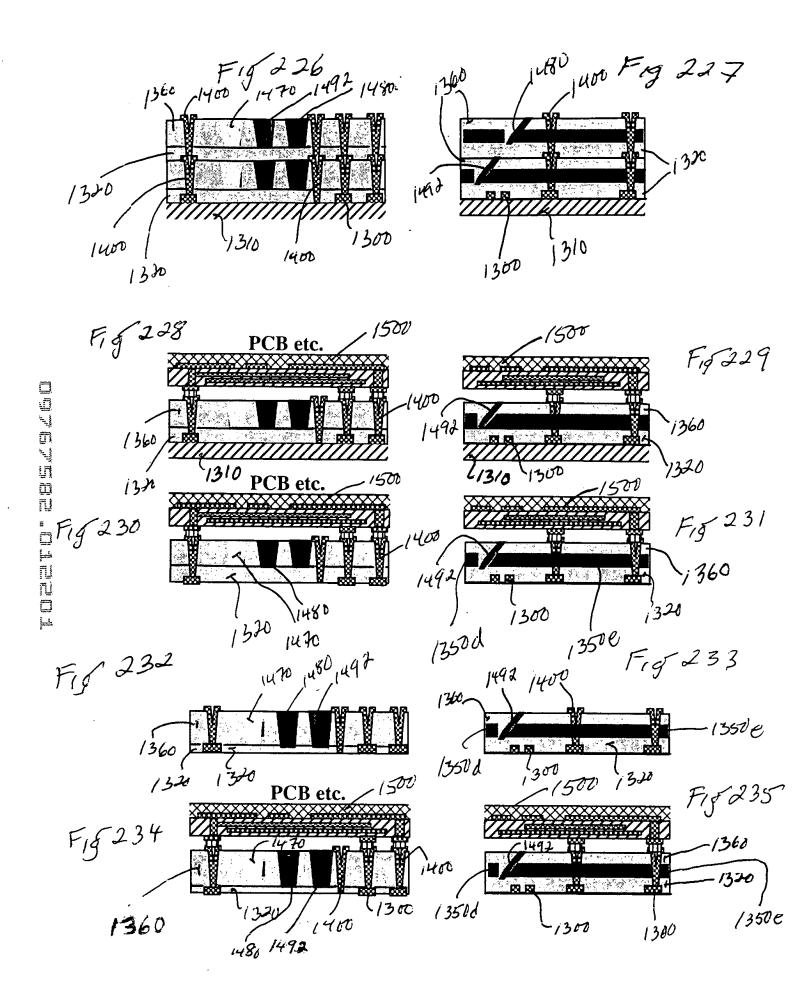
I/O Connection in OE Substrate (Active OE Layer, WDM)











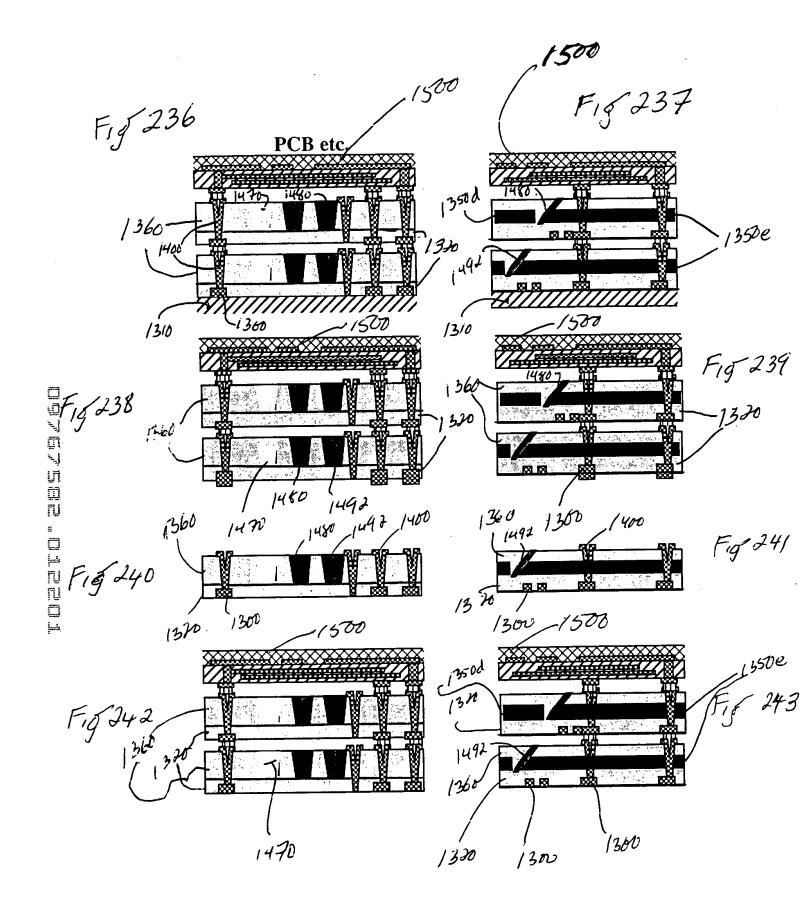
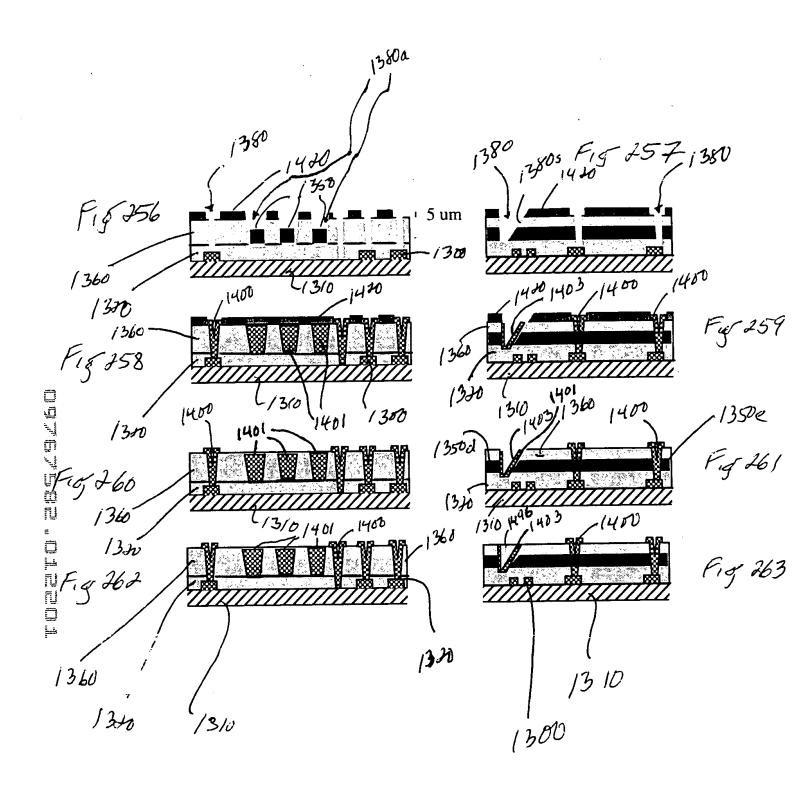
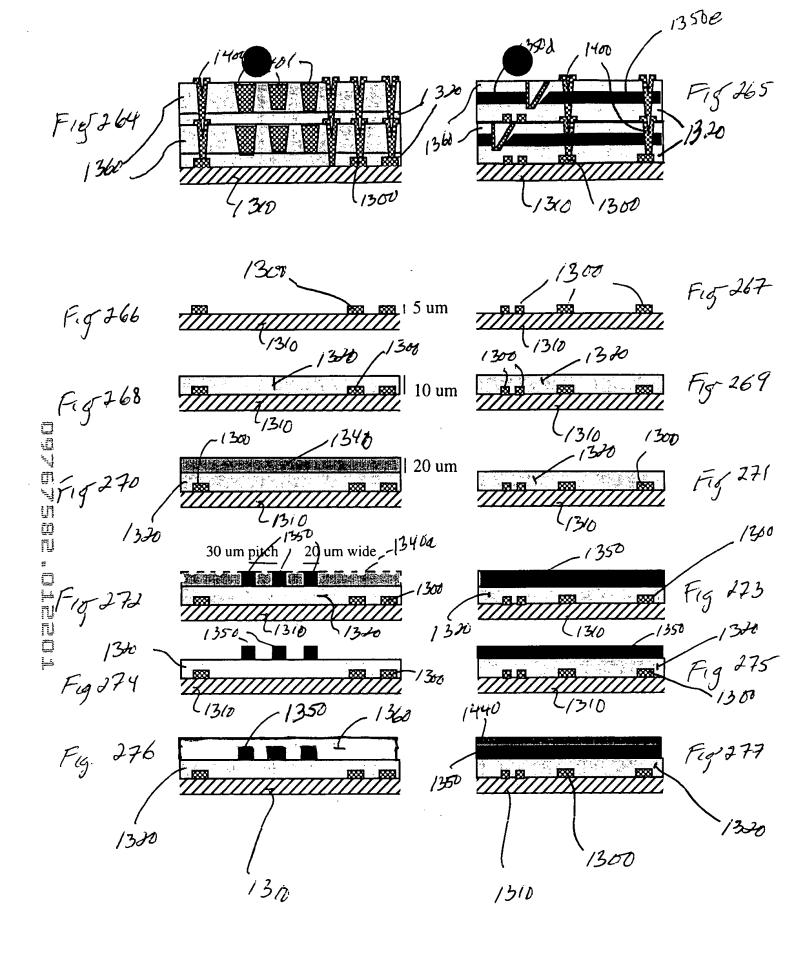
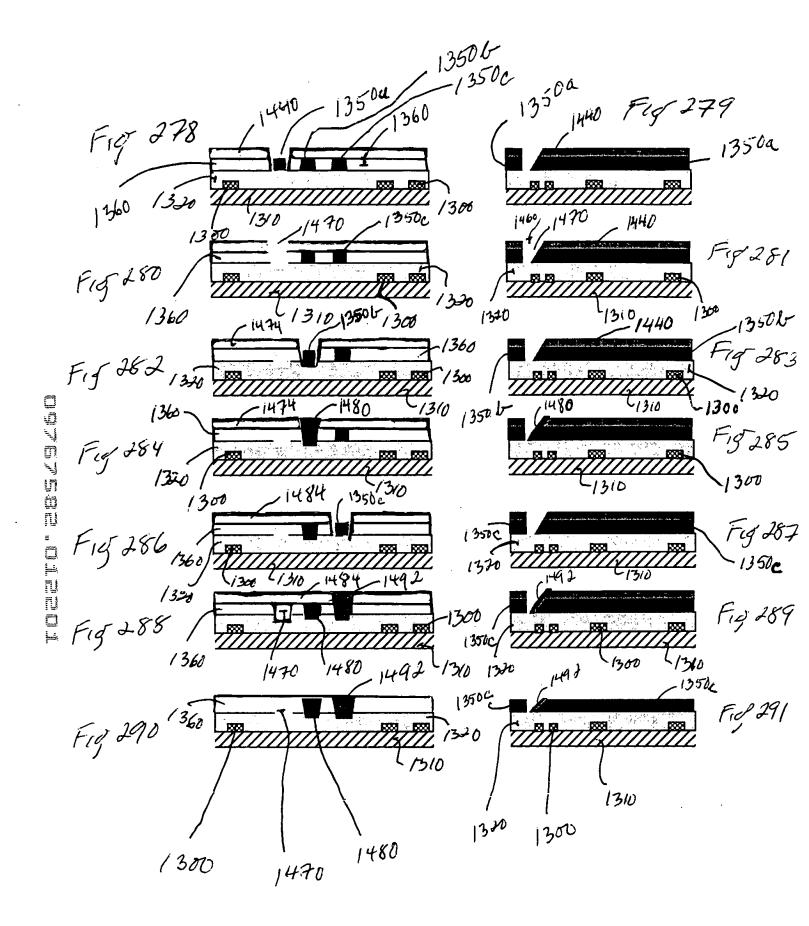
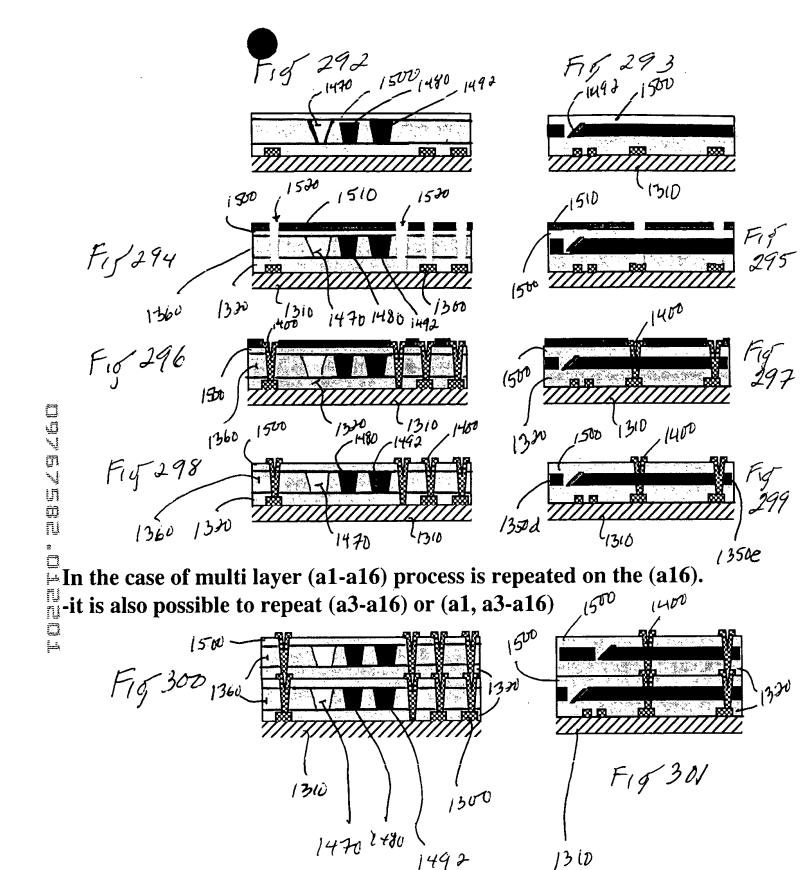


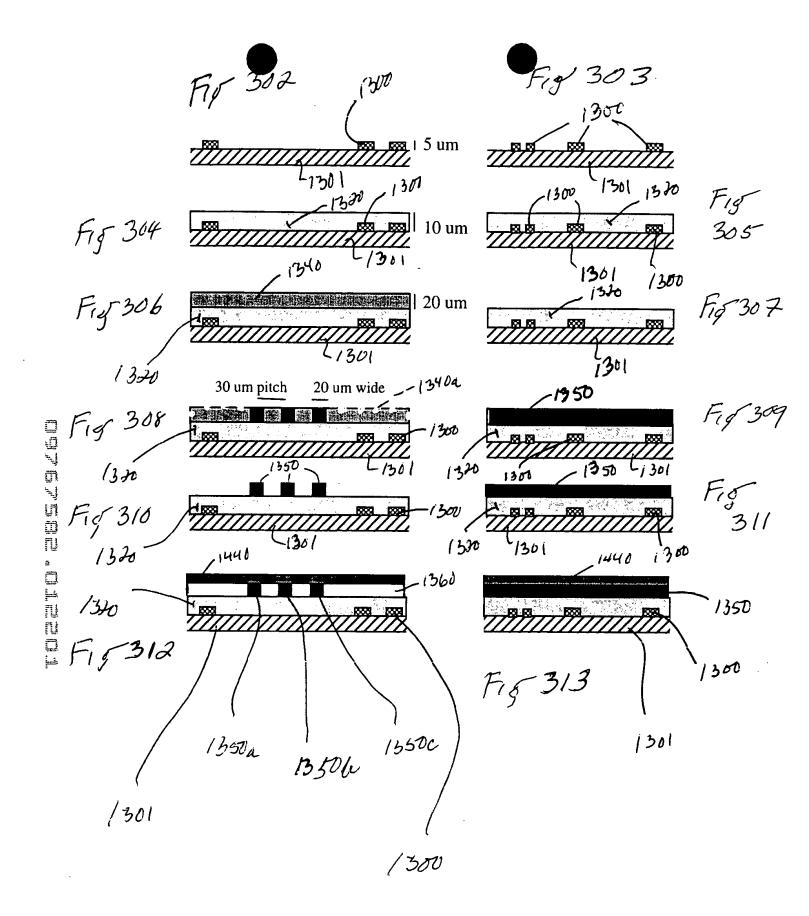
Fig 244 📆 I 5 um 300 L/310 10 um -1340 | 20 um 1300 (320 1348 9 30 um pitch 1310 1360 1350 1350 1360 35 um 13/0 1310 1300 1300

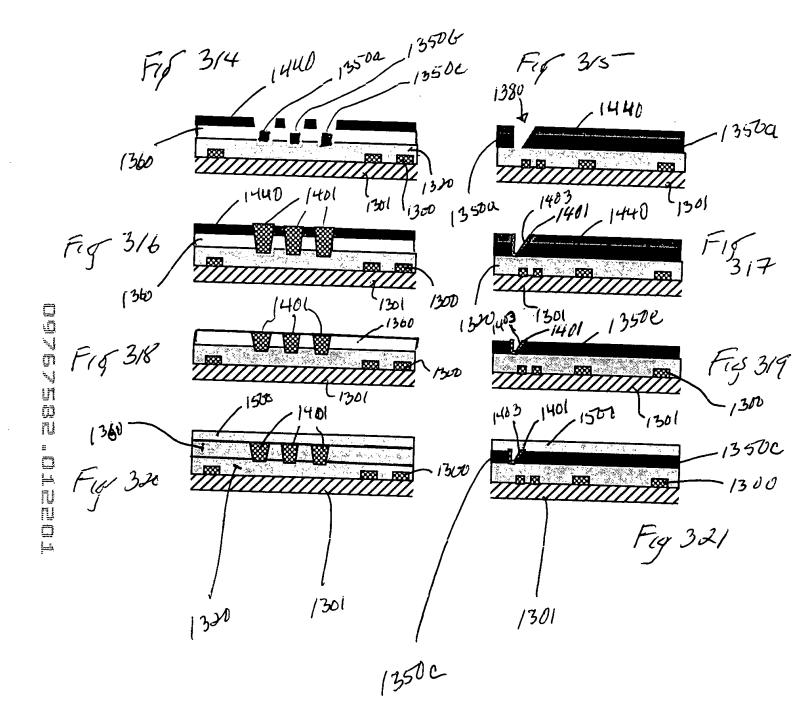


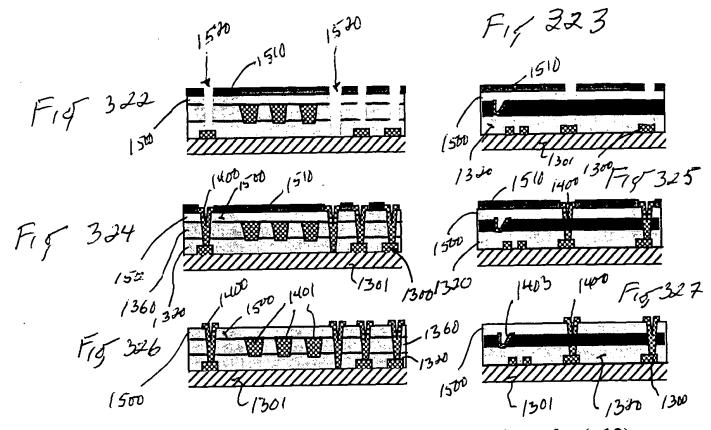






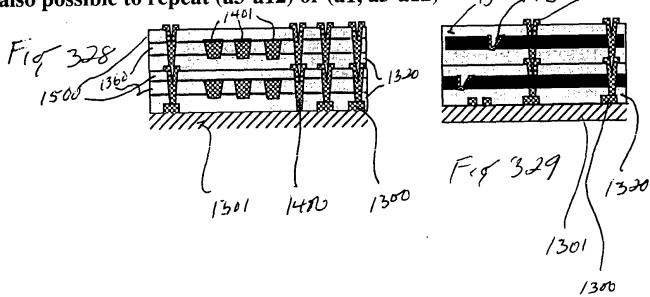




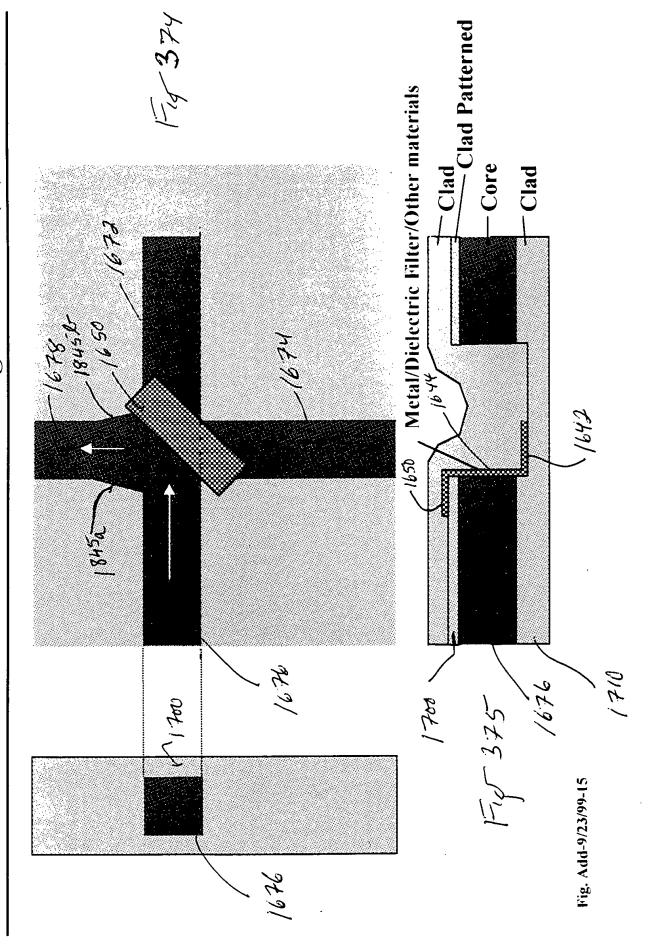


In the case of multi layer (a1-a12) process is repeated on the (a12).

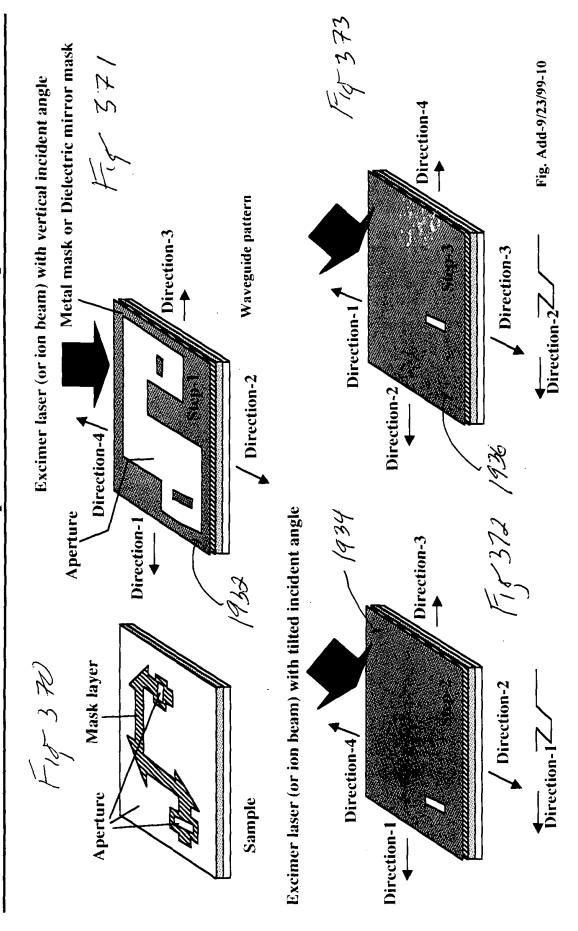
-it is also possible to repeat (a3-a12) or (a1, a3-a12)



Invented Corner Turning Structure (A)

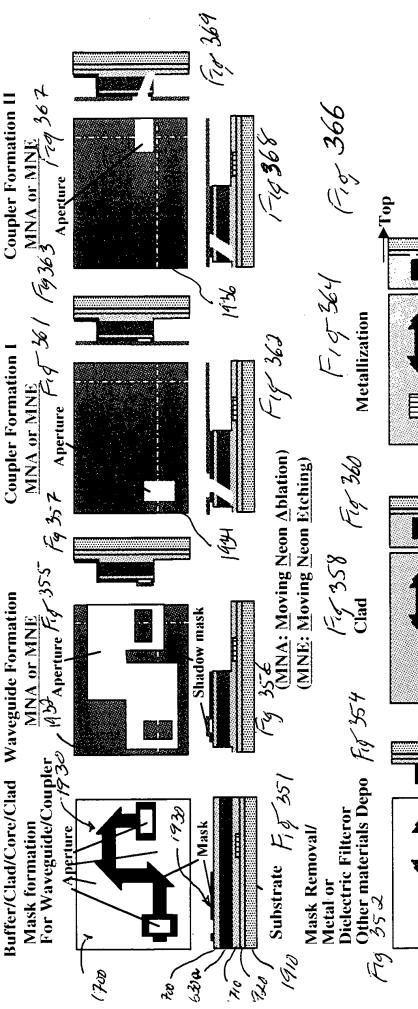


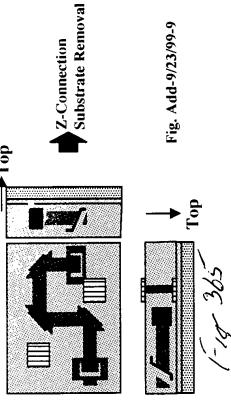
MNA, MNE Example for Add2 example



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Another Process Flow for Structure (II) 258,

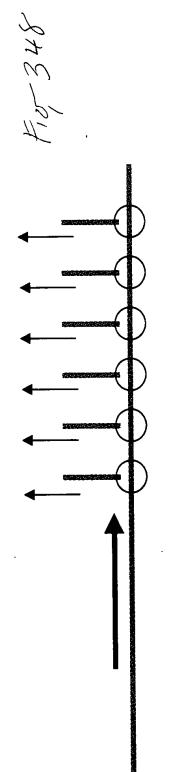




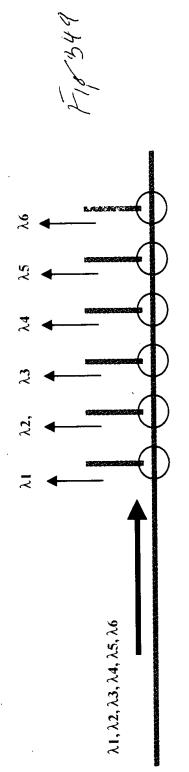
353

FUJITSU Computer Packaging Technologies, Inc.

Excimer Laser Ablation Example for Beveled Cut (2)



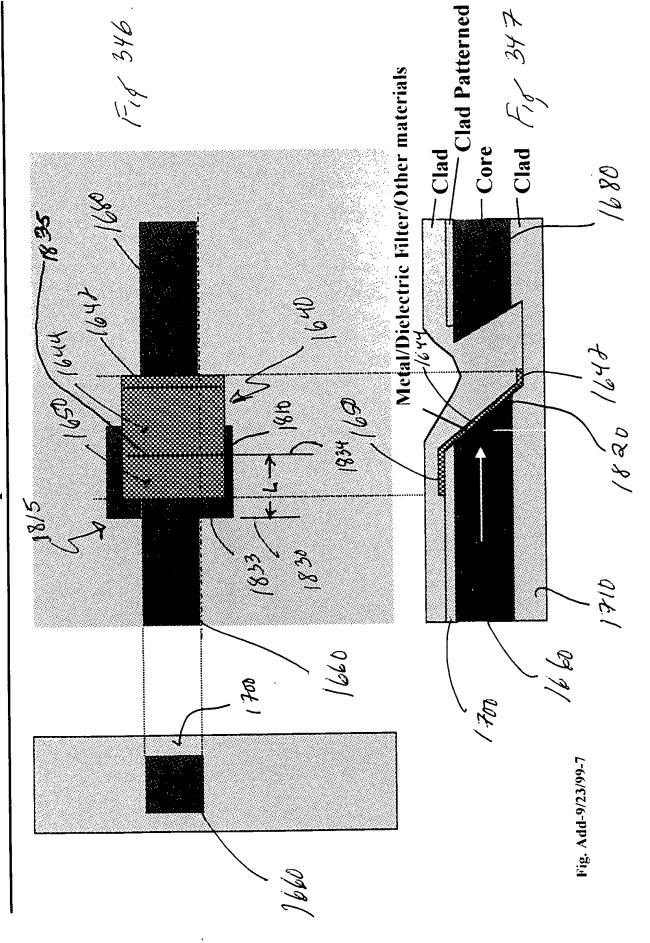
Beam Splitter



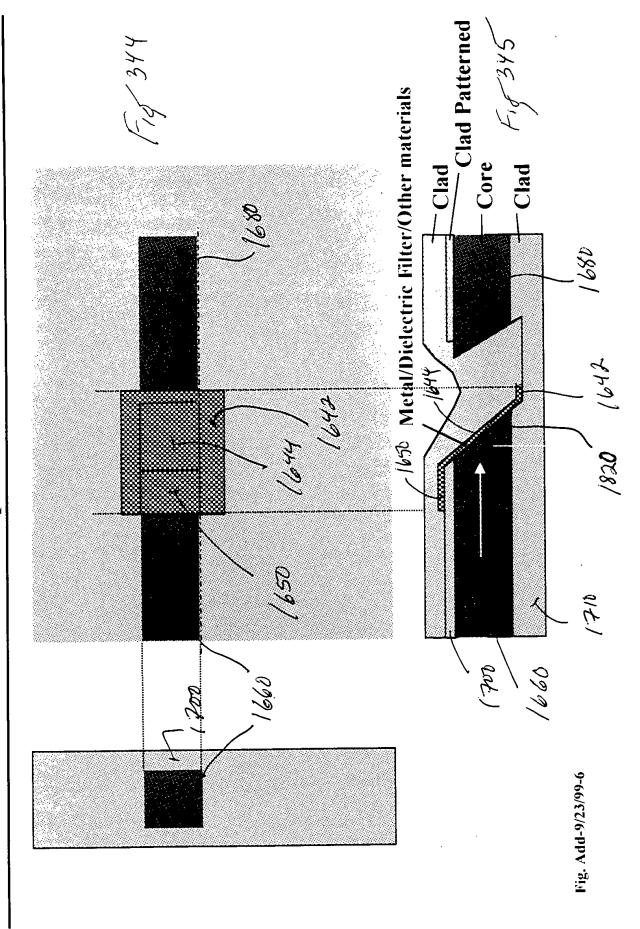
WDM DEMAX

Fig. Add-9/23/99-8

Invented Coupler Structure (II)

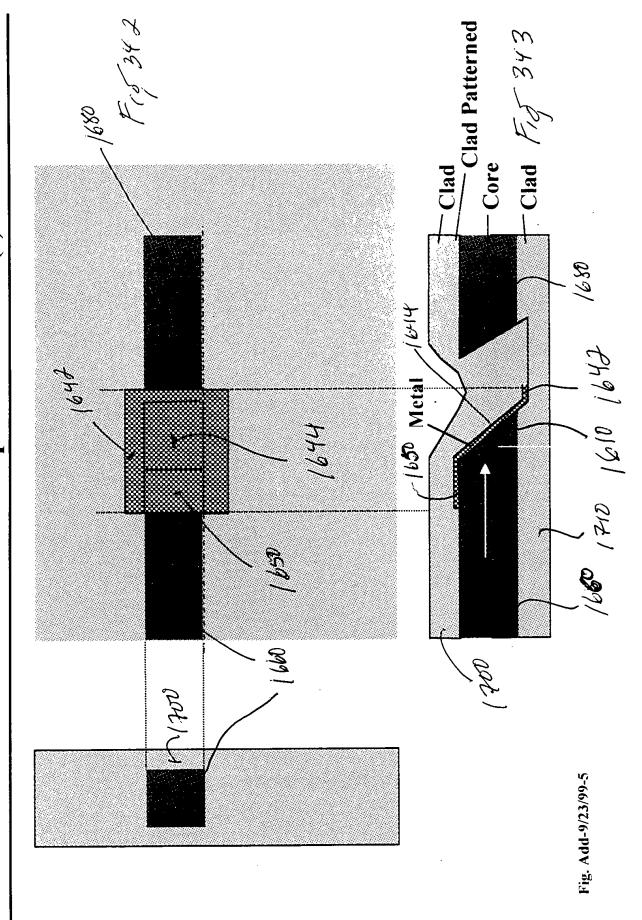


Invented Coupler Structure (I)



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Conventional Coupler Structure (I)



Invented Corner Turning Structure (II)

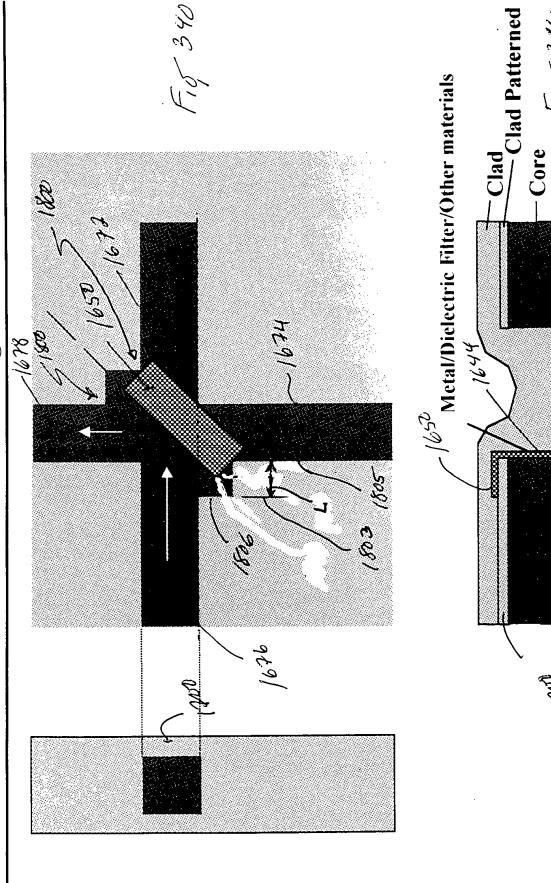
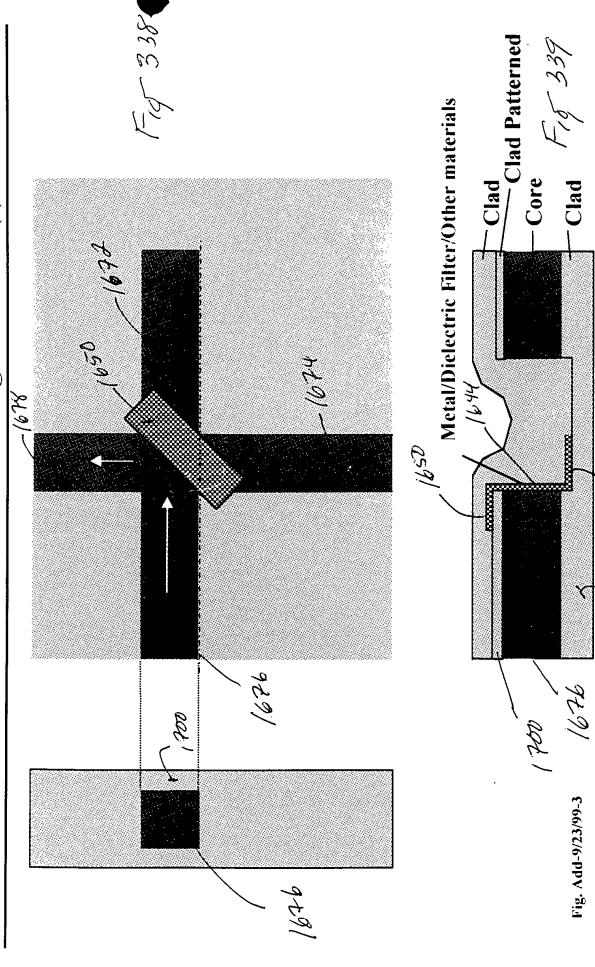


Fig. Add-9/23/99-4

Fig 341

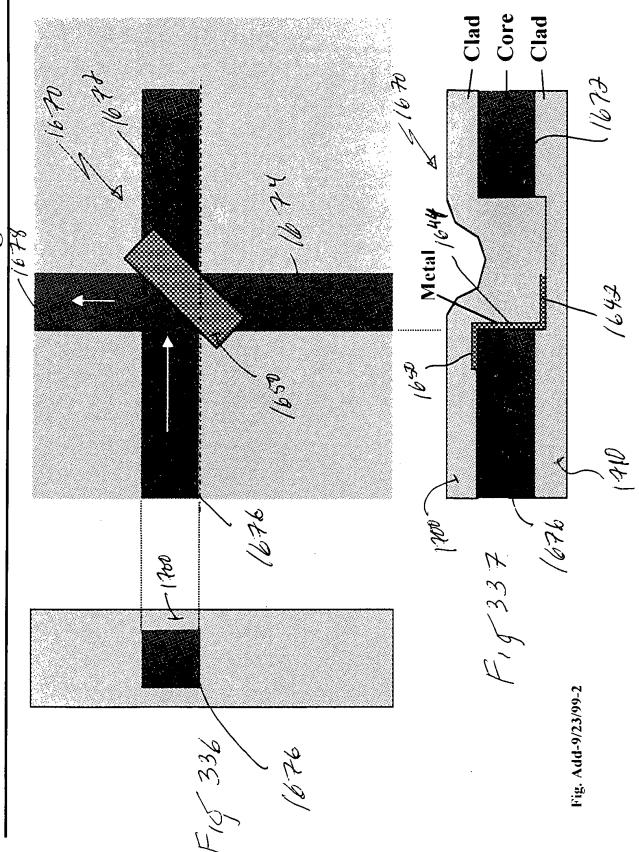
-Clad

Invented Corner Turning Structure (I)



FUJITSU Computer Packaging Technologies, Inc.

Conventional Corner Turning Structure



Conventional and Invented Waveguide Structure Examples

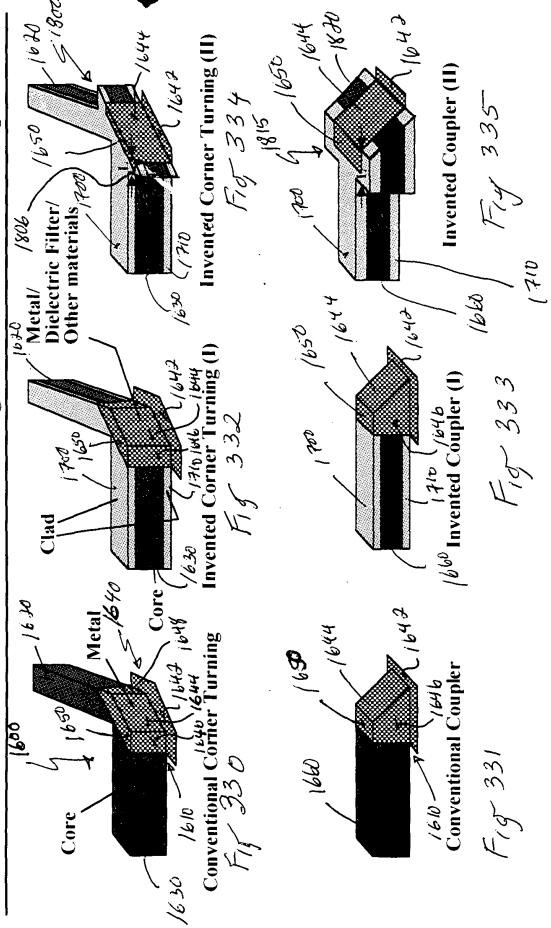
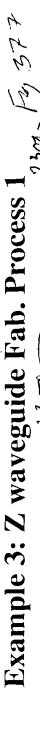
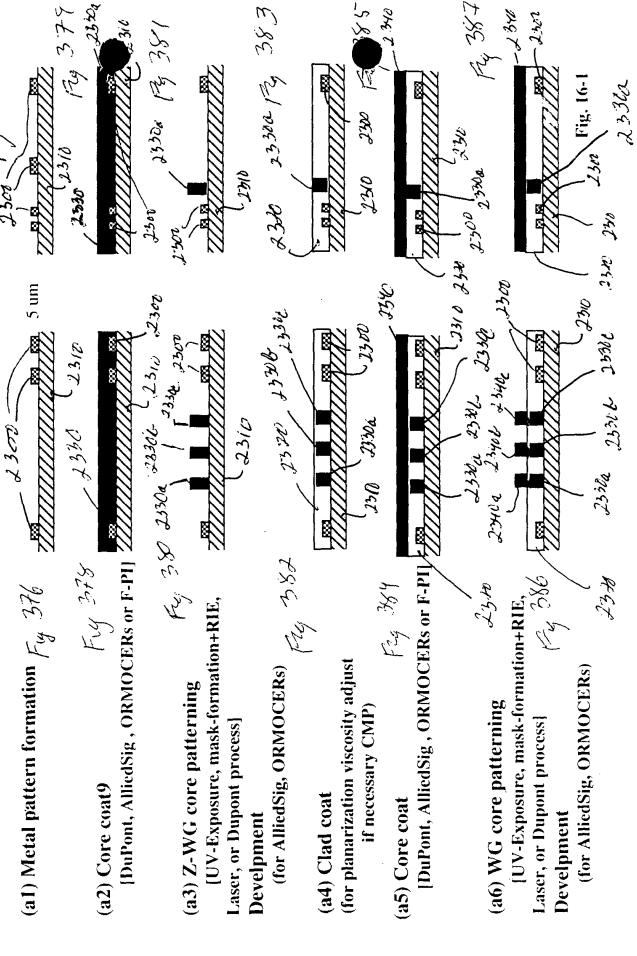


Fig. Add-9/23/99-1





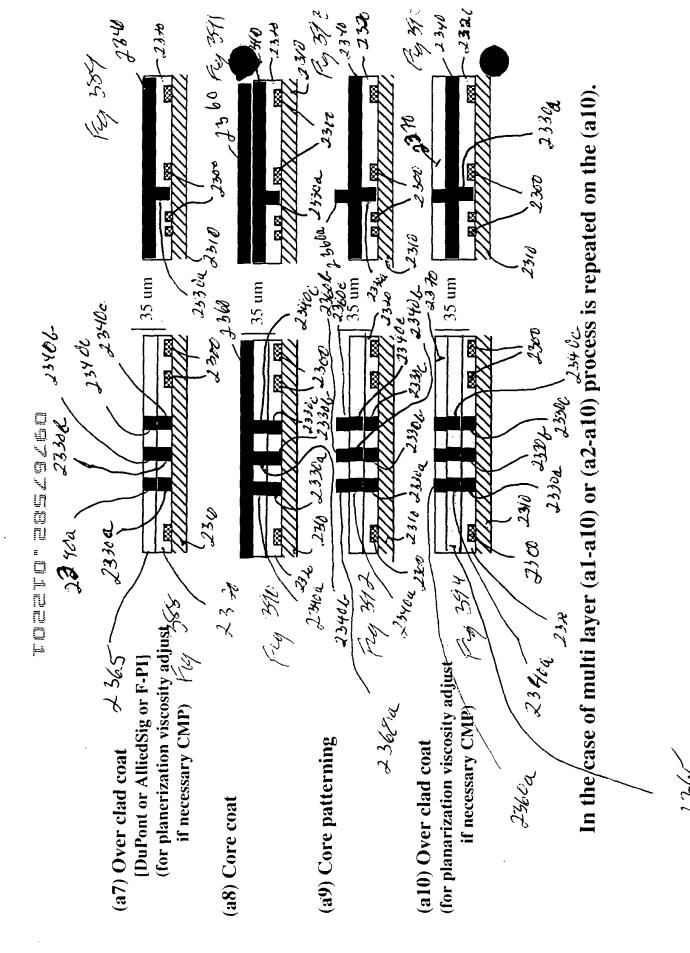
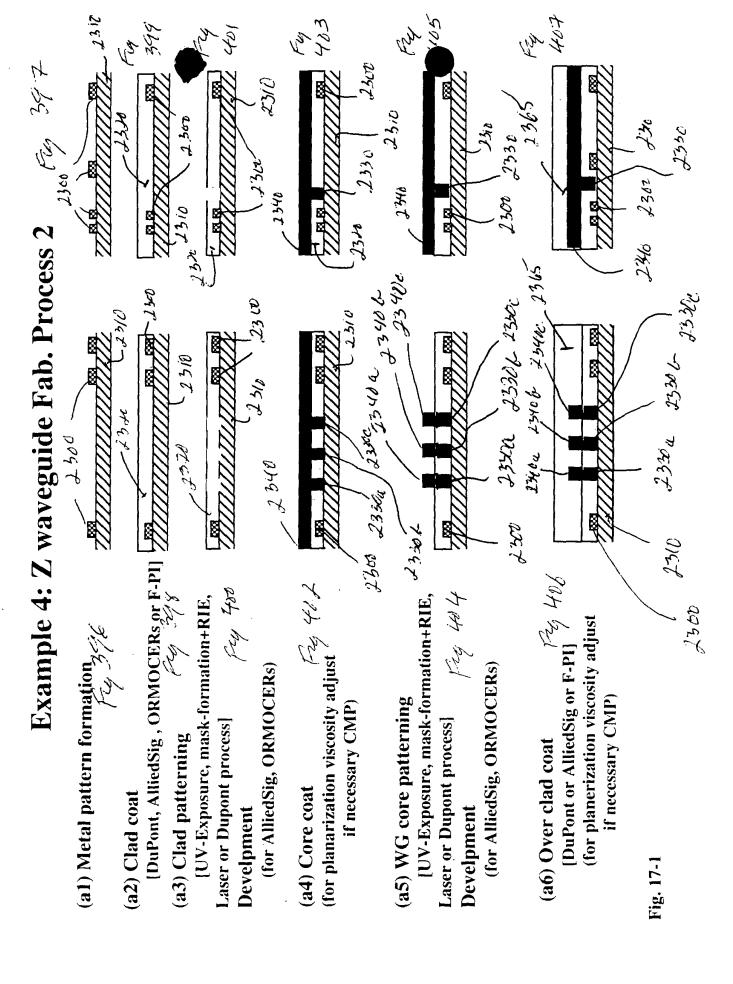
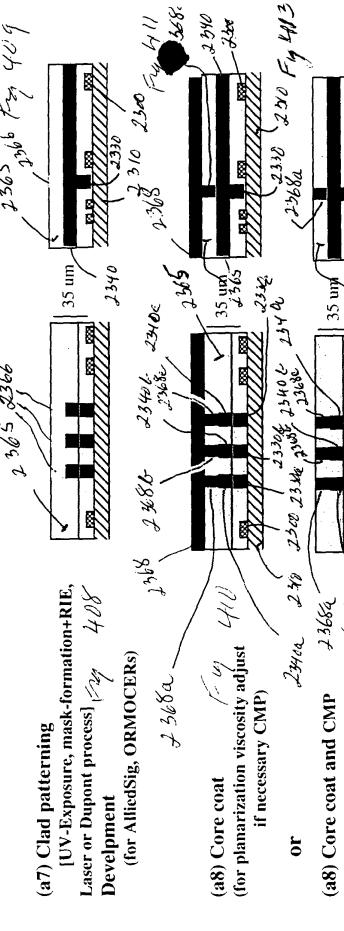


Fig. 16-2





In the case of multi layer (a1, a5-a8) or (a5-a8) process is repeated on the (a8).

2326

2300

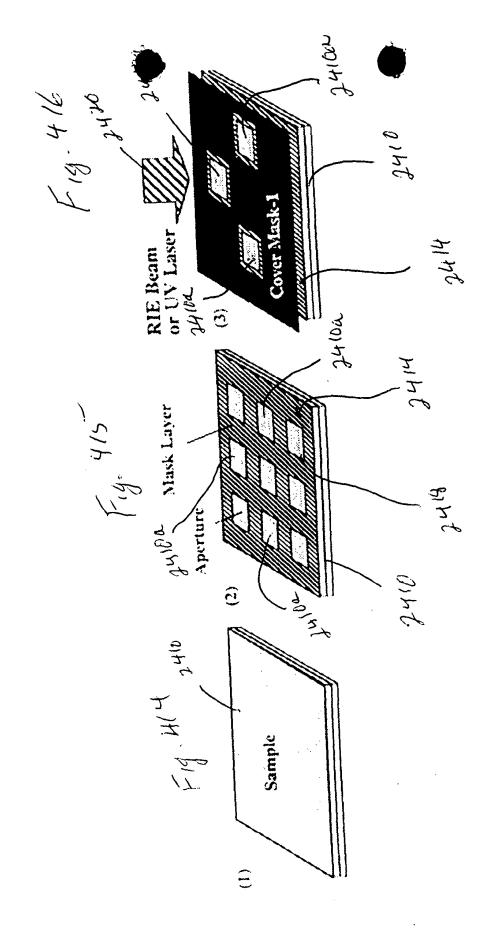
2710

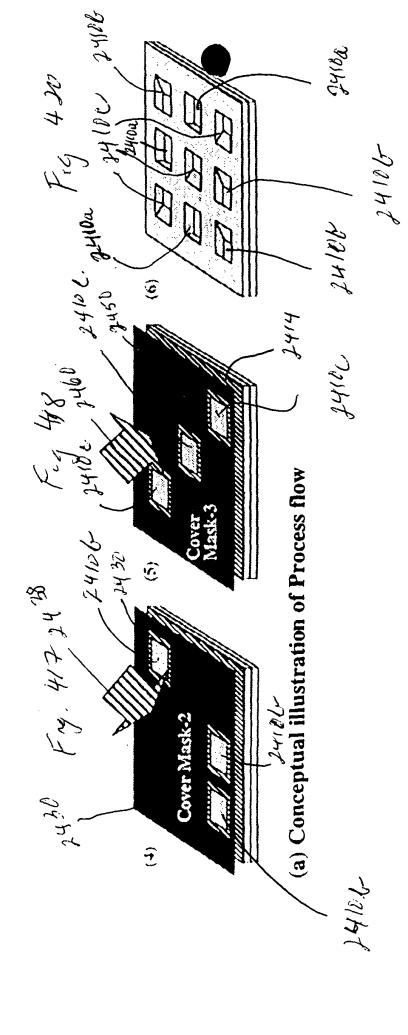
320

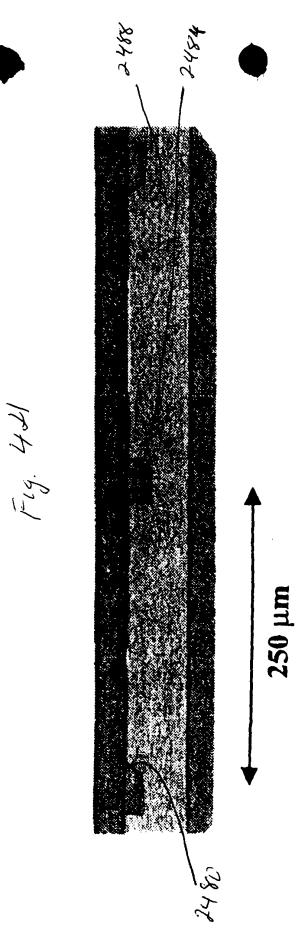
2310

235a

2365







(b) Trench wall formation of three different angles